

GD25LQ256C

GD25LQ256C

DATASHEET



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1.8V Uniform Sector **Dual and Quad Serial Flash**

1. FEATURES

- 256M-bit Serial Flash
 -32768K-byte
 -256 bytes per programmable page
- Standard, Dual, Quad SPI, QPI
 Standard SPI: SCLK, CS#, SI, SO, WP#, HOLD#
 Dual SPI: SCLK, CS#, IO0, IO1, WP#, HOLD#
 Quad SPI: SCLK, CS#, IO0, IO1, IO2, IO3
 QPI: SCLK, CS#, IO0, IO1, IO2, IO3
- High Speed Clock Frequency
 -120MHz for fast read with 30PF load
 -Dual I/O Data transfer up to 240Mbits/s
 -Quad I/O Data transfer up to 480Mbits/s
 -QPI Mode Data transfer up to 480Mbits/s
 -Continuous Read With 8/16/32/64-byte Wrap
- Software/Hardware Write Protection
 -Write protect all/portion of memory via software
 -Enable/Disable protection with WP# Pin
 -Top or Bottom, Sector or Block selection
- Minimum 100,000 Program/Erase Cycles

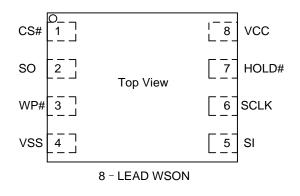
- Program/Erase Speed
 Page Program time: 0.7ms typical
 Sector Erase time: 90ms typical
 Block Erase time: 0.3/0.5s typical
 Chip Erase time: 200s typical
- Flexible Architecture
 -Sector of 4K-byte
 -Block of 32/64k-byte
 -Erase/Program Suspend/Resume
- Low Power Consumption
 -20mA maximum active current
 -10uA maximum power down current
- Advanced security Features
 -64-Bit Customer ID
 -3*512-Byte Security Registers With OTP Lock
- Single Power Supply Voltage
 Full voltage range:1.65~2.0V



2. GENERAL DESCRIPTION

The GD25LQ256C (256M-bit) Serial flash supports the standard Serial Peripheral Interface (SPI), and supports the Dual/Quad SPI and QPI mode: Serial Clock, Chip Select, Serial Data I/O0 (SI), I/O1 (SO), I/O2 (WP#), and I/O3 (HOLD#). The Dual I/O data is transferred with speed of 240Mbits/s and the Quad I/O & Quad output data is transferred with speed of 480Mbits/s.

CONNECTION DIAGRAM

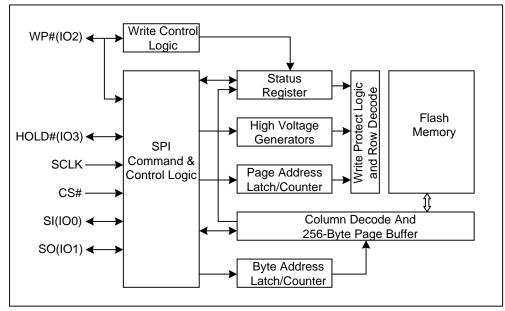


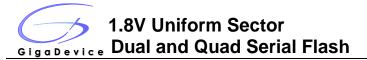
PIN DESCRIPTION

Pin Name	I/O	Description	
CS#	1	Chip Select Input	
SO (IO1) I/O		Data Output (Data Input Output 1)	
WP# (IO2)	I/O	Write Protect Input (Data Input Output 2)	
VSS		Ground	
SI (IO0)	I/O	Data Input (Data Input Output 0)	
SCLK	1	Serial Clock Input	
HOLD# (IO3)	I/O	Hold Input (Data Input Output 3)	
VCC		Power Supply	



BLOCK DIAGRAM





3. MEMORY ORGANIZATION

GD25LQ256C

Each device has	Each block has	Each sector has	Each page has	
32M	64/32K	4K	256	bytes
128K	256/128	16	-	pages
8192	16/8	-	-	sectors
512/1024	-	-	-	blocks

UNIFORM BLOCK SECTOR ARCHITECTURE GD25LQ256C 64K Bytes Block Sector Architecture

Block	Sector	Address range		
	8191	1FFF000H	1FFFFFFH	
511				
	8176	1FF0000H	1FF0FFFH	
	8175	1FEF000H	1FEFFFFH	
510				
	8160	1FE0000H	1FE0FFFH	
	47	02F000H	02FFFFH	
2				
	32	020000H	020FFFH	
	31	01F000H	01FFFFH	
1				
	16	010000H	010FFFH	
	15	00F000H	00FFFFH	
0				
	0	000000H	000FFFH	

4. DEVICE OPERATION

SPI Mode

Standard SPI

The GD25LQ256C features a serial peripheral interface on 4 signals bus: Serial Clock (SCLK), Chip Select (CS#), Serial Data Input (SI) and Serial Data Output (SO). Both SPI bus mode 0 and 3 are supported. Input data is latched on the rising edge of SCLK and data shifts out on the falling edge of SCLK.

Dual SPI

The GD25LQ256C supports Dual SPI operation when using the "Dual Output Fast Read" and "Dual I/O Fast Read" (3BH and BBH) commands. These commands allow data to be transferred to or from the device at two times the rate of the standard SPI. When using the Dual SPI command the SI and SO pins become bidirectional I/O pins: IO0 and IO1. **Quad SPI**

The GD25LQ256C supports Quad SPI operation when using the "Quad Output Fast Read", "Quad I/O Fast Read", "Quad I/O Word Fast Read", "Quad Page Program" (6BH, EBH, E7H, 32H) commands. These commands allow data to be transferred to or from the device at four times the rate of the standard SPI. When using the Quad SPI command the SI and SO pins become bidirectional I/O pins: IO0 and IO1, and WP# and HOLD# pins become IO2 and IO3. Quad SPI commands require the non-volatile Quad Enable bit (QE) in Status Register to be set.

QPI

The GD25LQ256C supports Quad Peripheral Interface (QPI) operations only when the device is switched from Standard/Dual/Quad SPI mode to QPI mode using the "Enable the QPI (38H)" command. The QPI mode utilizes all four IO pins to input the command code. Standard/Dual/Quad SPI mode and QPI mode are exclusive. Only one mode can be active at any given times. "Enable the QPI (38H)" and "Disable the QPI (FFH)" commands are used to switch between these two modes. Upon power-up and after software reset using ""Reset (99H)" command, the default state of the device is Standard/Dual/Quad SPI mode requires the non-volatile Quad Enable bit (QE) in Status Register to be set. **Hold**

The HOLD# signal goes low to stop any serial communications with the device, but doesn't stop the operation of write status register, programming, or erasing in progress.

The operation of HOLD, need CS# keep low, and starts on falling edge of the HOLD# signal, with SCLK signal being low (if SCLK is not being low, HOLD operation will not start until SCLK being low). The HOLD condition ends on rising edge of HOLD# signal with SCLK being low (If SCLK is not being low, HOLD operation will not end until SCLK being low).

The SO is high impedance, both SI and SCLK don't care during the HOLD operation, if CS# drives high during HOLD operation, it will reset the internal logic of the device. To re-start communication with chip, the HOLD# must be at high and then CS# must be at low.

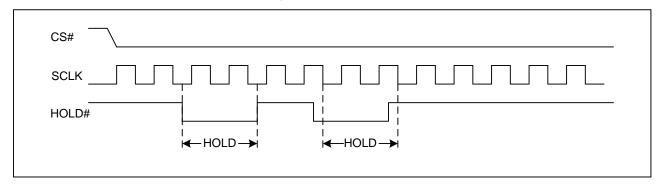


Figure1. Hold Condition

5. DATA PROTECTION

The GD25LQ256C provide the following data protection methods:

- Write Enable (WREN) command: The WREN command is set the Write Enable Latch bit (WEL). The WEL bit will
 return to reset by the following situation:
 - -Power-Up
 - -Write Disable (WRDI)
 - -Write Status Register (WRSR)
 - -Page Program (PP)
 - -Sector Erase (SE) / Block Erase (BE) / Chip Erase (CE)
 - -Erase Security Registers / Program Security Registers
- Software Protection Mode: The Block Protect (BP4, BP3, BP2, BP1, and BP0) bits define the section of the memory array that can be read but not change.
- ◆ Hardware Protection Mode: WP# going low to protected the BP0~BP4 bits and SRP0~1 bits.
- Deep Power-Down Mode: In Deep Power-Down Mode, all commands are ignored except the Release from Deep Power-Down Mode command.

ę	Status R	egister	Conten	t	Memory Content					
BP4 BP3 BP2 BP1 BP0		Blocks	Addresses	Density	Portion					
Х	Х	0	0	0	NONE	NONE	NONE	NONE		
0	0	0	0	1	504 to 511	1F80000H-1FFFFFFH	512KB	Upper 1/64		
0	0	0	1	0	495 to 511	1F00000H-1FFFFFFH	1MB	Upper 1/32		
0	0	0	1	1	479 to 511	1E00000H-1FFFFFFH	2MB	Upper 1/16		
0	0	1	0	0	447 to 511	1C00000H-1FFFFFH	4MB	Upper 1/8		
0	0	1	0	1	384 to 511	1800000H-1FFFFFFH	8MB	Upper 1/4		
0	0	1	1	0	256 to 511	1000000H-1FFFFFH	16MB	Upper 1/2		
0	1	0	0	1	0 to 7	000000H-07FFFFH	512KB	Lower 1/64		
0	1	0	1	0	0 to 15	000000H-0FFFFH	1MB	Lower 1/32		
0	1	0	1	1	0 to 31	000000H-1FFFFH	2MB	Lower 1/16		
0	1	1	0	0	0 to 63	000000H-3FFFFFH	4MB	Lower 1/8		
0	1	1	0	1	0 to 127	000000H-7FFFFH	8MB	Lower 1/4		
0	1	1	1	0	0 to 255	000000H-0FFFFFH	16MB	Lower 1/2		
Х	Х	1	1	1	0 to 511	000000H-1FFFFFFH	32MB	ALL		
1	0	0	0	1	511	1FFF000H-1FFFFFFH	4KB	Top Block		
1	0	0	1	0	511	1FFE000H-1FFFFFFH	8KB	Top Block		
1	0	0	1	1	511	1FFC000H-1FFFFFFH	16KB	Top Block		
1	0	1	0	Х	511	1FF8000H-1FFFFFFH	32KB	Top Block		
1	0	1	1	0	511	1FF8000H-1FFFFFFH	32KB	Top Block		
1	1	0	0	1	0	000000H-000FFFH	4KB	Bottom Block		
1	1	0	1	0	0	000000H-001FFFH	8KB	Bottom Block		
1	1	0	1	1	0	000000H-003FFFH	16KB	Bottom Block		
1	1	1	0	Х	0	000000H-007FFFH	32KB	Bottom Block		

Table1. GD25LQ256C Protected area size (CMP=0)

A 1 A A B A B A A A

1.8V Uniform Sector

 GigaDevice
 Dual and Quad Serial Flash
 GD25LQ256C

 1
 1
 1
 0
 0
 000000H-007FFFH
 32KB
 Bottom Block

	Table1a. GD25LQ256C Protected area size (CMP=1)										
:	Status F	Register	Conten	t		Memory Conte	nt				
BP4	BP3	BP2	BP1	BP0	Blocks	Addresses	Density	Portion			
Х	Х	0	0	0	0 to 511	000000H-1FFFFFH	ALL	ALL			
0	0	0	0	1	0 to 503	000000H-1F7FFFFH	32256KB	Lower 63/64			
0	0	0	1	0	0 to 494	000000H-1EFFFFH	31MB	Lower 31/32			
0	0	0	1	1	0 to 478	000000H-1DFFFFFH	30MB	Lower 15/16			
0	0	1	0	0	0 to 446	000000H-1BFFFFFH	28MB	Lower 7/8			
0	0	1	0	1	0 to 383	000000H-17FFFFFH	24MB	Lower 3/4			
0	0	1	1	0	0 to 254	000000H-0FFFFFH	16MB	Lower 1/2			
0	1	0	0	1	8 to 511	080000H-1FFFFFFH	32256KB	Upper 63/64			
0	1	0	1	0	16 to 511	100000H-1FFFFFFH	31MB	Upper 31/32			
0	1	0	1	1	32 to 511	200000H-1FFFFFFH	30MB	Upper 15/16			
0	1	1	0	0	64 to 511	400000H-1FFFFFH	28MB	Upper 7/8			
0	1	1	0	1	128 to 511	800000H-1FFFFFFH	24MB	Upper 3/4			
0	1	1	1	0	256 to 511	1000000H-1FFFFFFH	16MB	Upper 1/2			
Х	Х	1	1	1	NONE	NONE	NONE	NONE			
1	0	0	0	1	0 to 511	000000H-1FFEFFFH	32764KB	L-4095/4096			
1	0	0	1	0	0 to 511	000000H-1FFDFFFH	32760KB	L-2047/2048			
1	0	0	1	1	0 to 511	000000H-1FFBFFFH	32752KB	L-1023/1024			
1	0	1	0	Х	0 to 511	000000H-1FF7FFFH	32736KB	L-511/512			
1	0	1	1	0	0 to 511	000000H-1FF7FFFH	32736KB	L-511/512			
1	1	0	0	1	0 to 511	001000H-1FFFFFFH	32764KB	U-4095/4096			
1	1	0	1	0	0 to 511	002000H-1FFFFFFH	32760KB	U-2047/2048			
1	1	0	1	1	0 to 511	004000H-1FFFFFFH	32752KB	U-1023/1024			
1	1	1	0	Х	0 to 511	008000H-1FFFFFFH	32736KB	U-511/512			
1	1	1	1	0	0 to 511	008000H-1FFFFFH	32736KB	U-511/512			

6. Status Register

S15	S14	S13	S12	S11	S10	S9	S8
SUS1	СМР	LB3	LB2	EN4B	SUS2	QE	SRP1
S7	S6	S 5	S4	S3	S2	S1	S0
SRP0	BP4	BP3	BP2	BP1	BP0	WEL	WIP

The status and control bits of the Status Register are as follows: **WIP bit.**

The Write in Progress (WIP) bit indicates whether the memory is busy in program/erase/write status register progress. When WIP bit sets to 1, means the device is busy in program/erase/write status register progress, when WIP bit sets 0, means the device is not in program/erase/write status register progress.

WEL bit.

The Write Enable Latch (WEL) bit indicates the status of the internal Write Enable Latch. When set to 1 the internal Write Enable Latch is set, when set to 0 the internal Write Enable Latch is reset and no Write Status Register, Program or Erase command is accepted.

BP4, BP3, BP2, BP1, BP0 bits.

The Block Protect (BP4, BP3, BP2, BP1, and BP0) bits are non-volatile. They define the size of the area to be software protected against Program and Erase commands. These bits are written with the Write Status Register (WRSR) command. When the Block Protect (BP4, BP3, BP2, BP1, BP0) bits are set to 1, the relevant memory area (as defined in Table1).becomes protected against Page Program (PP), Sector Erase (SE) and Block Erase (BE) commands. The Block Protect (BP4, BP3, BP2, BP1, and BP0) bits can be written provided that the Hardware Protected mode has not been set. The Chip Erase (CE) command is executed, if the Block Protect (BP2, BP1, BP0) bits and CMP are all 0 or all 1.

SRP1, SRP0 bits.

The Status Register Protect (SRP1 and SRP0) bits are non-volatile Read/Write bits in the status register. The SRP bits control the method of write protection: software protection, hardware protection, power supply lock-down or one time programmable protection.

SRP1	SRP0	#WP	Status Register	Description
0	0	х	Software Protected	The Status Register can be written to after a Write Enable command, WEL=1.(Default)
0	1	0	Hardware Protected	WP#=0, the Status Register locked and can not be written to.
0	1	1	Hardware Unprotected	WP#=1, the Status Register is unlocked and can be written to after a Write Enable command, WEL=1.
1	0	х	Power Supply Lock-Down(1)	Status Register is protected and can not be written to again until the next Power-Down, Power-Up cycle.
1	I 1 X One Time Program(2)		One Time Program(2)	Status Register is permanently protected and can not be written to.

NOTE:

1. When SRP1, SRP0= (1, 0), a Power-Down, Power-Up cycle will change SRP1, SRP0 to (0, 0) state.

2. This feature is available on special order. Please contact GigaDevice for details.



QE bit.

The Quad Enable (QE) bit is a non-volatile Read/Write bit in the Status Register that allows Quad operation. When the QE bit is set to 0 (Default) the WP# pin and HOLD# pin are enable. When the QE pin is set to 1, the Quad IO2 and IO3 pins are enabled. (The QE bit should never be set to 1 during standard SPI or Dual SPI operation if the WP# or HOLD# pins are tied directly to the power supply or ground)

LB2, LB3, bits.

The LB2, LB3, bits are non-volatile One Time Program (OTP) bits in Status Register (S12-S13) that provide the write protect control and status to the Security Registers. The default state of LB2-LB3 are 0, the security registers are unlocked. The LB2-LB3 bits can be set to 1 individually using the Write Register instruction. The LB2-LB3 bits are One Time Programmable, once its set to 1, the Security Registers will become read-only permanently.

CMP bit

The CMP bit is a non-volatile Read/Write bit in the Status Register (S14). It is used in conjunction the BP4-BP0 bits to provide more flexibility for the array protection. Please see the Status registers Memory Protection table for details. The default setting is CMP=0.

SUS1, SUS2 bit

The SUS1 and SUS2 bit are read only bit in the status register (S15 and S10) that are set to 1 after executing an Erase/Program Suspend (75H) command (The Erase Suspend will set the SUS1 to 1,and the Program Suspend will set the SUS2 to 1). The SUS1 and SUS2 bit are cleared to 0 by Erase/Program Resume (7AH) command as well as a power-down, power-up cycle.

EN4B bit

The EN4B bit is a volatile Read/Write bit in the status register (S11) that is set to 1 after executing the Enable 4-byte Mode command, and cleared to 0 (default) by the Disable 4-byte Mode command as well as a power-down, power-up cycle.

7. COMMANDS DESCRIPTION

All commands, addresses and data are shifted in and out of the device, beginning with the most significant bit on the first rising edge of SCLK after CS# is driven low. Then, the one-byte command code must be shifted in to the device, most significant bit first on SI, each bit being latched on the rising edges of SCLK.

See Table2, every command sequence starts with a one-byte command code. Depending on the command, this might be followed by address bytes, or by data bytes, or by both or none. CS# must be driven high after the last bit of the command sequence has been shifted in. For the command of Read, Fast Read, Read Status Register or Release from Deep Power-Down, and Read Device ID, the shifted-in command sequence is followed by a data-out sequence. CS# can be driven high after any bit of the data-out sequence is being shifted out.

For the command of Page Program, Sector Erase, Block Erase, Chip Erase, Write Status Register, Write Enable, Write Disable or Deep Power-Down command, CS# must be driven high exactly at a byte boundary, otherwise the command is rejected, and is not executed. That is CS# must driven high when the number of clock pulses after CS# being driven low is an exact multiple of eight. For Page Program, if at any time the input byte is not a full byte, nothing will happen and WEL will not be reset.

Command Name	Byte 1	Byte 2	Byte 3	Byte 4	Byte 5	Byte 6	n-Bytes
Write Enable	06H						
Write Disable	04H						
Volatile SR	50H						
Write Enable							
Read Status Register	05H	(S7-S0)					(continuous)
Read Status Register-1	35H	(S15-S8)					(continuous)
Write Status Register	01H	(S7-S0)	(S15-S8)				
Read Data	03H	A23-A16	A15-A8	A7-A0	(D7-D0)	(Next byte)	(continuous)
Fast Read	0BH	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)	(continuous)
Dual Output	3BH	A23-A16	A15-A8	A7-A0	dummy	(D7-D0) ⁽¹⁾	(continuous)
Fast Read							
Dual I/O	BBH	A23-A8 ⁽²⁾	A7-A0	(D7-D0) ⁽¹⁾			(continuous)
Fast Read			M7-M0 ⁽²⁾				
Quad Output	6BH	A23-A16	A15-A8	A7-A0	dummy	(D7-D0) ⁽³⁾	(continuous)
Fast Read							
Quad I/O	EBH	A23-A0	dummy ⁽⁵⁾	(D7-D0) ⁽³⁾			(continuous)
Fast Read		M7-M0 ⁽⁴⁾					
Quad I/O Word	E7H	A23-A0	dummy ⁽⁶⁾	(D7-D0) ⁽³⁾			(continuous)
Fast Read ⁽⁷⁾		M7-M0 ⁽⁴⁾					
Page Program	02H	A23-A16	A15-A8	A7-A0	(D7-D0)	Next byte	
Quad Page Program	32H	A23-A16	A15-A8	A7-A0	(D7-D0) ⁽³⁾		
Sector Erase	20H	A23-A16	A15-A8	A7-A0			
Block Erase(32K)	52H	A23-A16	A15-A8	A7-A0			
Block Erase(64K)	D8H	A23-A16	A15-A8	A7-A0			
Chip Erase	C7/60H						
Enable QPI	38H						
Enable Reset	66H						
Reset	99H						
Set Burst with Wrap	77H	W6-W4					
Program/Erase	75H						
Suspend							
Program/Erase Resume	7AH						

Table2. Commands (Standard/Dual/Quad SPI) (3-byte mode)



GD25LQ256C

Release From Deep	ABH	dummy	dummy	dummy	(ID7-ID0)		(continuous)
Power-Down, And							
Read Device ID							
Release From Deep	ABH						
Power-Down							
Deep Power-Down	B9H						
Manufacturer/	90H	dummy	dummy	00H	(M7-M0)	(ID7-ID0)	(continuous)
Device ID		-					
Manufacturer/	0011	A 3 3 A 9	A7-A0,	(M7-M0)			(continuous)
Device ID by Dual I/O	92H	A23-A8	M[7:0]	(ID7-ID0)			(continuous)
Manufacturer/	94H	A23-A0,	dummy	(M7-M0)			(a a ntinua a a)
Device ID by Quad I/O	94⊓	M[7:0]		(ID7-ID0)			(continuous)
Read Identification	9FH	(M7-M0)	(ID15-ID8)	(ID7-ID0)			(continuous)
Read Serial Flash	5AH	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)	(continuous)
Discoverable							
Parameter ⁽¹⁰⁾							
Erase Security	44H	A23-A16	A15-A8	A7-A0			
Registers ⁽⁸⁾							
Program Security	42H	A23-A16	A15-A8	A7-A0	(D7-D0)	(D7-D0)	
Registers ⁽⁸⁾					, ,	× ,	
Read Security	48H	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)	
Registers ⁽⁸⁾					-		
Enable 4-byte Mode	B7H						
Disable 4-byte Mode	E9H						

Table2.1. Commands (Standard/Dual/Quad SPI) (4-byte mode)

	Dute 4	Dute 0	Dute 0	Dute 4	Dute 5	Dute 0	Dute 7
Command Name	Byte 1	Byte 2	Byte 3	Byte 4	Byte 5	Byte 6	Byte 7
Read Data	03H	A31-A24	A23-A16	A15-A8	A7-A0	(D7-D0)	(Next byte)
Fast Read	0BH	A31-A24	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)
Dual Output Fast Read	3BH	A31-A24	A23-A16	A15-A8	A7-A0	dummy	(D7-D0) ⁽¹⁾
Dual I/O Fast Read	BBH	A31-A24	A23-A8 ⁽²⁾	A7-A0 M7-M0 ⁽²⁾	(D7-D0) ⁽¹⁾		
Quad Output Fast Read	6BH	A31-A24	A23-A16	A15-A8	A7-A0	dummy	(D7-D0) ⁽³⁾
Quad I/O Fast Read	EBH	A31-A0	M7-M0 ⁽⁴⁾	dummy ⁽⁵⁾	(D7-D0) ⁽³⁾		
Quad I/O Word Fast Read ⁽⁷⁾	E7H	A31-A0	M7-M0 ⁽⁴⁾	dummy ⁽⁶⁾	(D7-D0) ⁽³⁾		
Page Program	02H	A31-A24	A23-A16	A15-A8	A7-A0	(D7-D0)	Next byte
Quad Page Program	32H	A31-A24	A23-A16	A15-A8	A7-A0	(D7-D0) ⁽³⁾	
Sector Erase	20H	A31-A24	A23-A16	A15-A8	A7-A0		
Block Erase(32K)	52H	A31-A24	A23-A16	A15-A8	A7-A0		
Block Erase(64K)	D8H	A31-A24	A23-A16	A15-A8	A7-A0		



Command Name	Byte 1	Byte 2	Byte 3	Byte 4	Byte 5	Byte 6
Clock Number	(0,1)	(2,3)	(4,5)	(6,7)	(8,9)	(10,11)
Write Enable	06H					
Volatile SR Write Enable	50H					
Write Disable	04H					
Read Status Register	05H	(S7-S0)				
Read Status Register-1	35H	(S15-S8)				
Read Status Register-2	15H	(S1-S0)				
Write Status Register	01H	(S7-S0)	(S15-S8)			
Page Program	02H	A23-A16	A15-A8	A7-A0	(D7-D0)	Next byte
Sector Erase	20H	A23-A16	A15-A8	A7-A0		
Block Erase(32K)	52H	A23-A16	A15-A8	A7-A0		
Block Erase(64K)	D8H	A23-A16	A15-A8	A7-A0		
Chip Erase	C7/60H					
Program/Erase Suspend	75H					
Program/Erase Resume	7AH					
Deep Power-Down	B9H					
Set Read Parameters	COH	P7-P0				
Fast Read	0BH	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)
Burst Read with Wrap	0CH	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)
Burst Read with Wrap for Lower 128Mb (A24=0)	8CH	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)
Burst Read with Wrap for Higher 128Mb (A24=1)	8DH	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)
Quad I/O Fast Read	EBH	A23-A16	A15-A8	A7-A0	M7-M0	(D7-D0)
Release From Deep Power-Down, And Read Device ID	ABH	dummy	dummy	dummy	(ID7-ID0)	
Manufacturer/ Device ID	90H	dummy	dummy	00H	(M7-M0)	(ID7-ID0)
Read Identification	9FH	(M7-M0)	(ID15-ID8)	(ID7-ID0)		
Read Serial Flash Discoverable Parameter ⁽¹⁰⁾	5AH	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)
Disable QPI	FFH					
Enable Reset	66H					
Reset	99H					
Enable 4-byte Mode	B7H					
Disable 4-byte Mode	E9H					

				-			
Command Name	Byte 1	Byte 2	Byte 3	Byte 4	Byte 5	Byte 6	Byte7
Clock Number	(0,1)	(2,3)	(4,5)	(6,7)	(8,9)	(10,11)	(12,13)
Page Program	02H	A31-A24	A23-A16	A15-A8	A7-A0	(D7-D0)	Next byte
Sector Erase	20H	A31-A24	A23-A16	A15-A8	A7-A0		
Block Erase(32K)	52H	A31-A24	A23-A16	A15-A8	A7-A0		
Block Erase(64K)	D8H	A31-A24	A23-A16	A15-A8	A7-A0		
Fast Read	0BH	A31-A24	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)
Burst Read with Wrap	0CH	A31-A24	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)
Quad I/O Fast Read	EBH	A31-A24	A23-A16	A15-A8	A7-A0	M7-M0	(D7-D0)



NOTE	E					
1. Du	al Output data					
	IO0 = (D6, D4, D2,	, D0)				
	IO1 = (D7, D5, D3,	, D1)				
2. Du	al Input Address					
	IO0 = A22, A20, A1	18, A16, A14, A12, A	10, A8	A6, A4, A2	2, A0, M6, M4, M2, M	ЛО
	IO1 = A23, A21, A1	19, A17, A15, A13, A	11, A9	A7, A5, A3	3, A1, M7, M5, M3, N	Л1
3. Qu	ad Output Data					
	IO0 = (D4, D0,	.)				
	IO1 = (D5, D1,	.)				
	IO2 = (D6, D2,	.)				
	IO3 = (D7, D3,))				
4. Qu	ad Input Address					
	IO0 = A20, A16, A1	12, A8, A4, A0, M4	, M0			
	IO1 = A21, A17, A1	13, A9, A5, A1, M5	, M1			
	IO2 = A22, A18, A1	14, A10, A6, A2, M6	, M2			
	IO3 = A23, A19, A1	15, A11, A7, A3, M7	M3			
5. Fas	st Read Quad I/O Dat	ta				
	100 = (x, x, x, x, D4	4, D0,)				
	IO1 = (x, x, x, x, D5	5, D1,)				
	IO2 = (x, x, x, x, D6	6, D2,)				
	103 = (x, x, x, x, D	7, D3,)				
6. Fas	st Word Read Quad I	/O Data				
	IO0 = (x, x, D4, D0),)				
	IO1 = (x, x, D5, D1	,)				
	IO2 = (x, x, D6, D2					
	IO3 = (x, x, D7, D3					
	st Word Read Quad I		address b	it must be ().	
8. See	curity Registers Addre					
					A8-A0=Byte Address	
				0011000b, <i>i</i>	A8-A0=Byte Address	3.
9. QP	I Command, Address					
		2 3 4 5	6 7	89	10 11	
	IO0 = C4, C0, A2				D4, D0,	
		21, A17, A13, A9,		D5, D1,		
		22, A18, A14, A10				
	103 = 07, 03, A2	23, A19, A15, A11	A7, A3,	D7, D3,	D7, D3	

10. Read Serial Flash Discoverable Parameter (SFDP) command is available on special order. Please contact GigaDevice if this function is needed.



1.8V Uniform Sector Dual and Quad Serial Flash

Table of ID Definitions:

GD25LQ256C

Operation Code	M7-M0	ID15-ID8	ID7-ID0
9FH	C8	60	19
90H	C8		18
ABH			18

7.1. Enable 4-byte Mode (B7H)

The Enable 4-byte Mode command enables accessing the address length of 32-bit for the memory area of the higher density (larger than 128Mb). The GD25LQ256C default is in 24-bit address mode. After sending the Enable 4-byte Mode command, the EN4B bit (S11) will be set to 1 to indicate the 4-byte address mode has been enabled. Once the 4-byte address mode is enabled, the address length becomes 32-bit instead of the default 24 bit. The Disable 4-byte mode or Reset or Power-off will disable 4-byte mode. In the 4-byte mode, A31-A25 are don't care.

Figure2. Enable 4-byte Mode Sequence Diagram

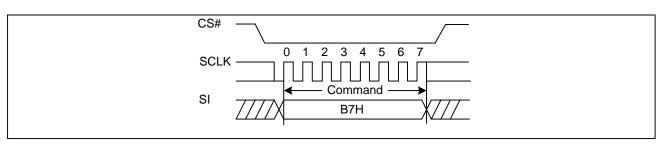
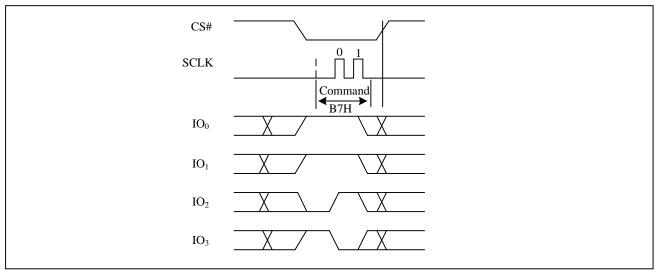


Figure2a. Enable 4-byte Mode Sequence Diagram (QPI)





7.2. Disable 4-byte Mode (E9H)

The Disable 4-byte Mode command is executed to exit the 4-byte address mode and return to the default 3-byte address mode. After sending the Disable 4-byte Mode command, the EN4B bit (S11) will be clear to be 0 to indicate the 4-byte address mode has been disabled, and then the address length will return to 24-bit.



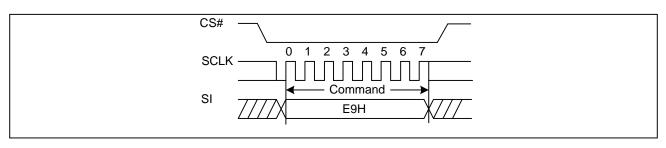
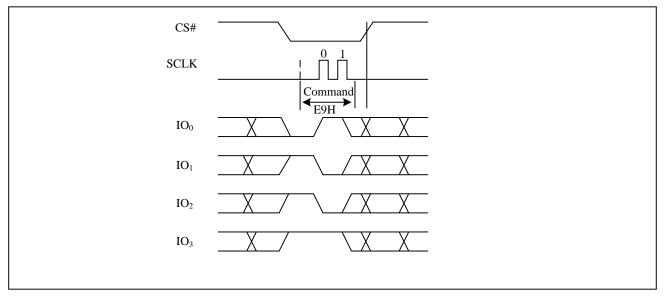


Figure3a. Disable 4-byte Mode Sequence Diagram (QPI)



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7.3. Write Enable (WREN) (06H)

The Write Enable (WREN) command is for setting the Write Enable Latch (WEL) bit. The Write Enable Latch (WEL) bit must be set prior to every Page Program (PP), Sector Erase (SE), Block Erase (BE), Chip Erase (CE), Write Status Register (WRSR) and Erase/Program Security Registers command. The Write Enable (WREN) command sequence: CS# goes low \rightarrow sending the Write Enable command \rightarrow CS# goes high.

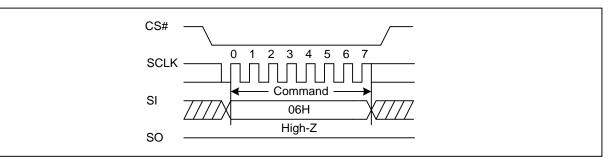
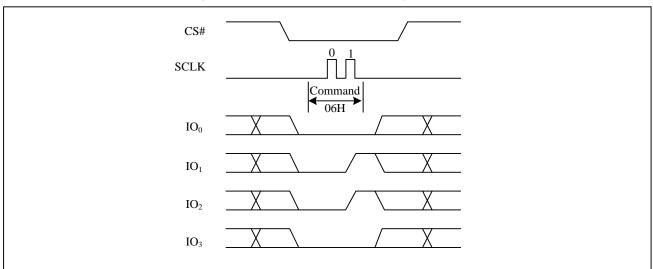


Figure4. Write Enable Sequence Diagram

Figure4a. Write Enable Sequence Diagram (QPI)



7.4. Write Disable (WRDI) (04H)

The Write Disable command is for resetting the Write Enable Latch (WEL) bit. The Write Disable command sequence: CS# goes low \rightarrow Sending the Write Disable command \rightarrow CS# goes high. The WEL bit is reset by following condition: Power-up and upon completion of the Write Status Register, Page Program, Sector Erase, Block Erase, Chip Erase, Erase/Program Security Registers and Reset commands.

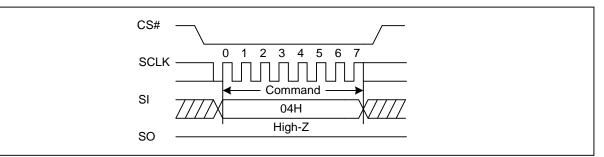
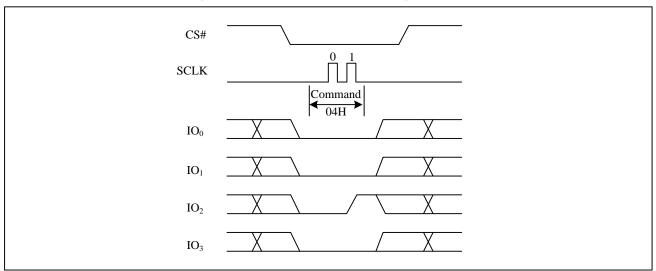


Figure5. Write Disable Sequence Diagram

Figure5a. Write Disable Sequence Diagram (QPI)



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7.5. Write Enable for Volatile Status Register (50H)

The non-volatile Status Register bits can also be written to as volatile bits. This gives more flexibility to change the system configuration and memory protection schemes quickly without waiting for the typical non-volatile bit write cycles or affecting the endurance of the Status Register non-volatile bits. The Write Enable for Volatile Status Register command must be issued prior to a Write Status Register command. The Write Enable for Volatile Status Register command will not set the Write Enable Latch bit, it is only valid for the Write Status Register command to change the volatile Status Register bit values.

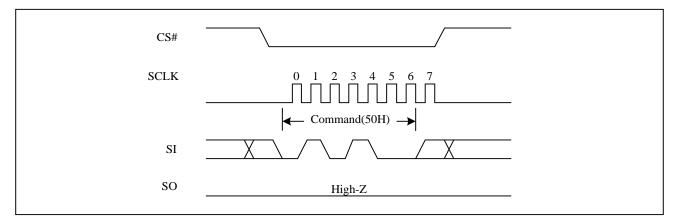
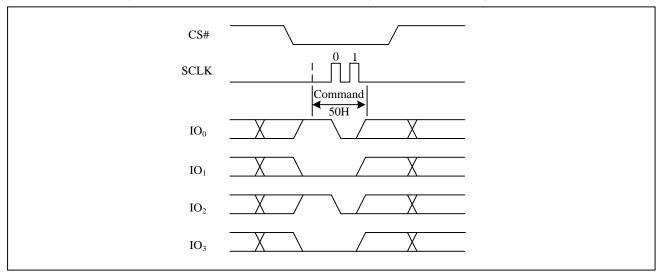


Figure6. Write Enable for Volatile Status Register Sequence Diagram

Figure6a. Write Enable for Volatile Status Register Sequence Diagram (QPI)



7.6. Read Status Register (RDSR) (05H or 35H or 15H)

The Read Status Register (RDSR) command is for reading the Status Register. The Status Register may be read at any time, even while a Program, Erase or Write Status Register cycle is in progress. When one of these cycles is in progress, it is recommended to check the Write in Progress (WIP) bit before sending a new command to the device. It is also possible to read the Status Register continuously. For command code "05H" / "35H", the SO will output Status Register bits S7~S0 / S15-S8. The command code "15H" only supports the QPI mode, the I/O0 will output Status Register S1-S0. (For 133MHz Frequency, the 15H will better than 05H to check the WIP bit)



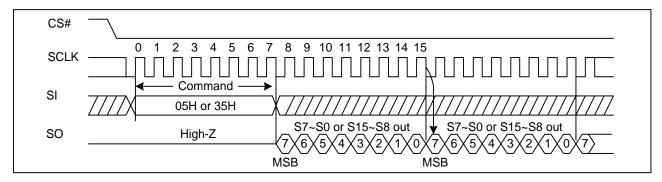
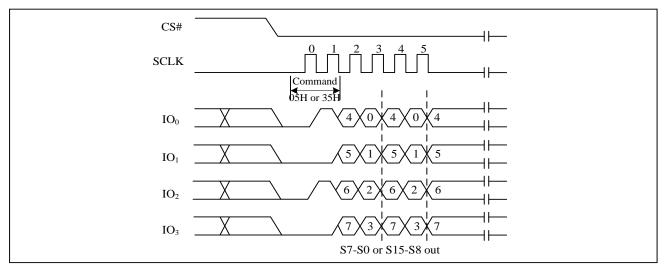


Figure7a. Read Status Register Sequence Diagram (QPI)



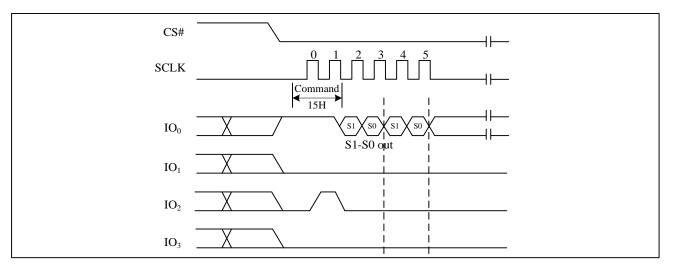


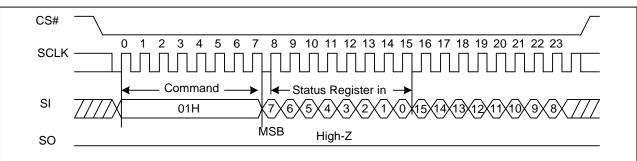
Figure7b. Read Status Register Sequence Diagram (QPI) (15H)

7.7. Write Status Register (WRSR) (01H)

The Write Status Register (WRSR) command allows new values to be written to the Status Register. Before it can be accepted, a Write Enable (WREN) command must previously have been executed. After the Write Enable (WREN) command has been decoded and executed, the device sets the Write Enable Latch (WEL).

The Write Status Register (WRSR) command has no effect on S15, S11, S10, S1 and S0 of the Status Register. CS# must be driven high after the eighth or sixteen bit of the data byte has been latched in. If not, the Write Status Register (WRSR) command is not executed. If CS# is driven high after eighth bit of the data byte, the CMP and QE bits will be cleared to 0 in SPI mode, while only CMP will be cleared to 0 in QPI mode. As soon as CS# is driven high, the self-timed Write Status Register cycle (whose duration is t_W) is initiated. While the Write Status Register cycle is in progress, the Status Register may still be read to check the value of the Write In Progress (WIP) bit. The Write In Progress (WIP) bit is 1 during the self-timed Write Status Register cycle, and is 0 when it is completed. When the cycle is completed, the Write Enable Latch (WEL) is reset.

The Write Status Register (WRSR) command allows the user to change the values of the Block Protect (BP4, BP3, BP2, BP1, and BP0) bits, to define the size of the area that is to be treated as read-only, as defined in Table1. The Write Status Register (WRSR) command also allows the user to set or reset the Status Register Protect (SRP1 and SRP0) bits in accordance with the Write Protect (WP#) signal. The Status Register Protect (SRP1 and SRP0) bits and Write Protect (WP#) signal allow the device to be put in the Hardware Protected Mode. The Write Status Register (WRSR) command is not executed once the Hardware Protected Mode is entered.

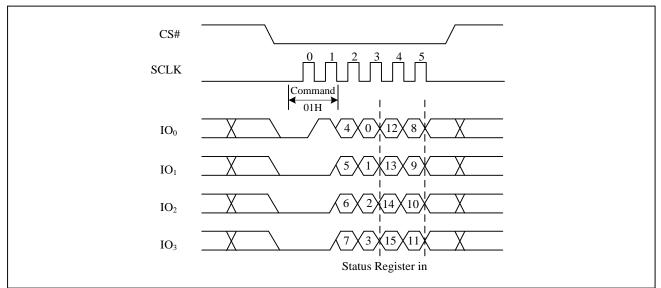






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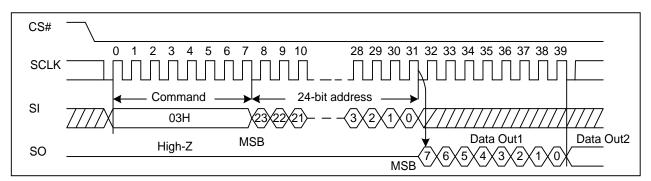
Figure8a. Write Status Register Sequence Diagram (QPI)



7.8. Read Data Bytes (READ) (03H)

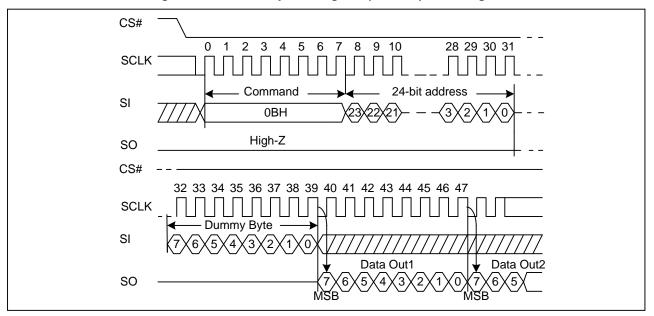
The Read Data Bytes (READ) command is followed by a 3-byte address (A23-A0) or a 4-byte address (A31-A0), each bit being latched-in during the rising edge of SCLK. Then the memory content, at that address, is shifted out on SO, each bit being shifted out, at a Max frequency f_R , during the falling edge of SCLK. The first byte addressed can be at any location. The address is automatically incremented to the next higher address after each byte of data is shifted out. The whole memory can, therefore, be read with a single Read Data Bytes (READ) command. Any Read Data Bytes (READ) command, while an Erase, Program or Write cycle is in progress, is rejected without having any effects on the cycle that is in progress.





7.9. Read Data Bytes at Higher Speed (Fast Read) (0BH)

The Read Data Bytes at Higher Speed (Fast Read) command is for quickly reading data out. It is followed by a 3-byte address (A23-A0) or a 4-byte address (A31-A0) and a dummy byte, each bit being latched-in during the rising edge of SCLK. Then the memory content, at that address, is shifted out on SO, each bit being shifted out, at a Max frequency fc, during the falling edge of SCLK. The first byte addressed can be at any location. The address is automatically incremented to the next higher address after each byte of data is shifted out.





Fast Read (0BH) in QPI mode

The Fast Read command is also supported in QPI mode. In QPI mode, the number of dummy clocks is configured by the "Set Read Parameters (C0H)" command to accommodate a wide range application with different needs for either maximum Fast Read frequency or minimum data access latency. Depending on the Read Parameter Bits P[5:4] setting, the number of dummy clocks can be configured as either 4/6/8/8.

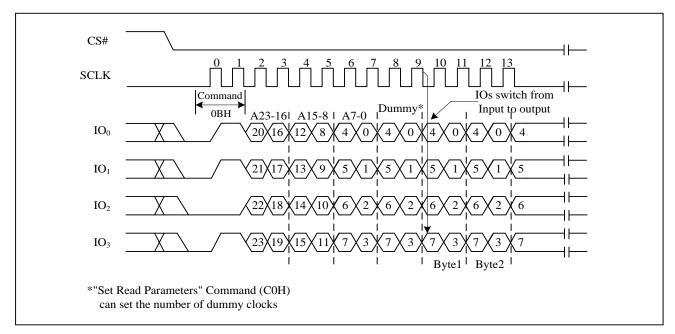


Figure10a. Read Data Bytes at Higher Speed Sequence Diagram (QPI)

Dual Output Fast Read (3BH) 7.10.

The Dual Output Fast Read command is followed by 3-byte address (A23-A0) or a 4-byte address (A31-A0)and a dummy byte, each bit being latched in during the rising edge of SCLK, then the memory contents are shifted out 2-bit per clock cycle from SI and SO. The command sequence is shown in followed Figure 11. The first byte addressed can be at any location. The address is automatically incremented to the next higher address after each byte of data is shifted out.

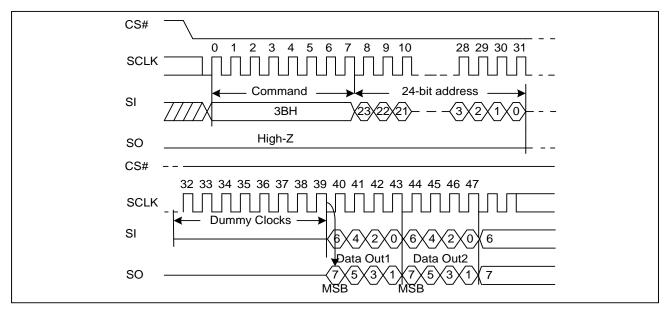


Figure11. Dual Output Fast Read Sequence Diagram

1.8V Uniform Sector GigaDevice Dual and Quad Serial Flash 7.11. Quad Output Fast Read (6BH)

The Quad Output Fast Read command is followed by 3-byte address (A23-A0) or a 4-byte address (A31-A0) and a dummy byte, each bit being latched in during the rising edge of SCLK, then the memory contents are shifted out 4-bit per clock cycle from IO3, IO2, IO1 and IO0. The command sequence is shown in followed Figure 12. The first byte addressed can be at any location. The address is automatically incremented to the next higher address after each byte of data is shifted out.

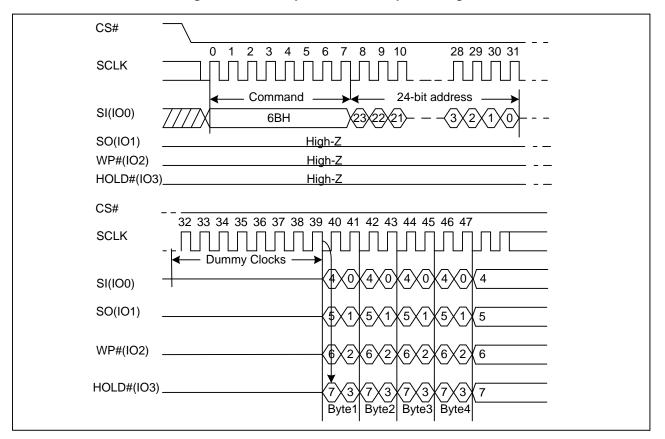


Figure12. Quad Output Fast Read Sequence Diagram

1.8V Uniform Sector GigaDevice Dual and Quad Serial Flash 7.12 Dual I/O East Boad (BBH)

7.12. Dual I/O Fast Read (BBH)

The Dual I/O Fast Read command is similar to the Dual Output Fast Read command but with the capability to input the 3-byte address (A23-0) or a 4-byte address (A31-A0) and a "Continuous Read Mode" byte 2-bit per clock by SI and SO, each bit being latched in during the rising edge of SCLK, then the memory contents are shifted out 2-bit per clock cycle from SI and SO. The command sequence is shown in followed Figure 13. The first byte addressed can be at any location. The address is automatically incremented to the next higher address after each byte of data is shifted out.

Dual I/O Fast Read with "Continuous Read Mode"

The Dual I/O Fast Read command can further reduce command overhead through setting the "Continuous Read Mode" bits (M7-0) after the input 3-byte address (A23-A0) or a 4-byte address (A31-A0). If the "Continuous Read Mode" bits (M5-4) = (1, 0), then the next Dual I/O Fast Read command (after CS# is raised and then lowered) does not require the BBH command code. The command sequence is shown in followed Figure 13a. If the "Continuous Read Mode" bits (M5-4) do not equal (1, 0), the next command requires the first BBH command code, thus returning to normal operation. A "Continuous Read Mode" Reset command can be used to reset (M5-4) before issuing normal command.

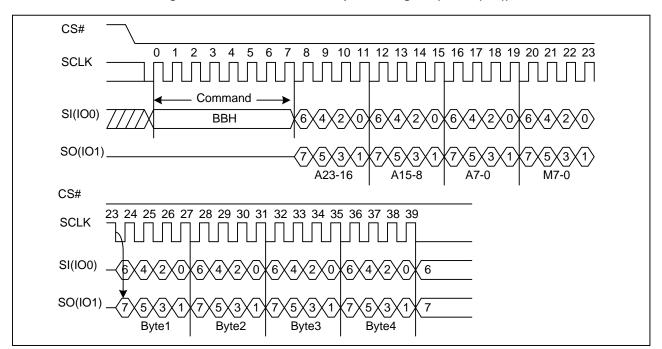
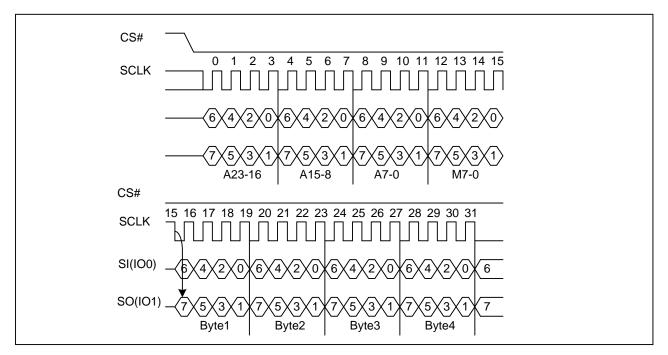


Figure13. Dual I/O Fast Read Sequence Diagram (M5-4≠ (1, 0))

Note: The device default is in 24-bit address mode. For 4-byte mode, the address length becomes 32-bit.



Figure13a. Dual I/O Fast Read Sequence Diagram (M5-4= (1, 0))



1.8V Uniform Sector GigaDevice Dual and Quad Serial Flash 7.13 Quad I/Q East Road (EBH)

7.13. Quad I/O Fast Read (EBH)

The Quad I/O Fast Read command is similar to the Dual I/O Fast Read command but with the capability to input the 3-byte address (A23-0) or a 4-byte address (A31-A0) and a "Continuous Read Mode" byte and 4-dummy clock 4-bit per clock by IO0, IO1, IO3, IO4, each bit being latched in during the rising edge of SCLK, then the memory contents are shifted out 4-bit per clock cycle from IO0, IO1, IO2, IO3. The command sequence is shown in followed Figure14. The first byte addressed can be at any location. The address is automatically incremented to the next higher address after each byte of data is shifted out. The Quad Enable bit (QE) of Status Register (S9) must be set to enable for the Quad I/O Fast read command.

Quad I/O Fast Read with "Continuous Read Mode"

The Quad I/O Fast Read command can further reduce command overhead through setting the "Continuous Read Mode" bits (M7-0) after the input 3-byte address (A23-A0) or a 4-byte address (A31-A0). If the "Continuous Read Mode" bits (M5-4) = (1, 0), then the next Quad I/O Fast Read command (after CS# is raised and then lowered) does not require the EBH command code. The command sequence is shown in followed Figure14a. If the "Continuous Read Mode" bits (M5-4) do not equal to (1, 0), the next command requires the first EBH command code, thus returning to normal operation. A "Continuous Read Mode" Reset command can be used to reset (M5-4) before issuing normal command.

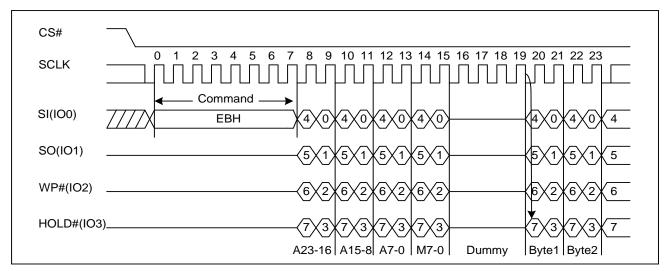
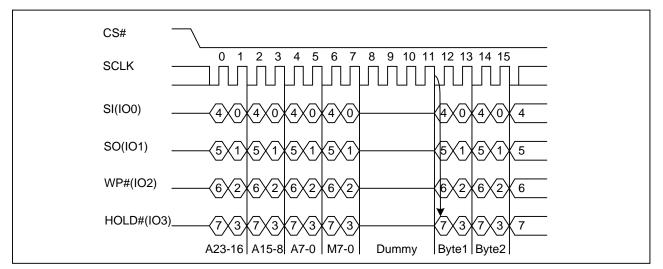


Figure14. Quad I/O Fast Read Sequence Diagram (M5-4≠ (1, 0))



1.8V Uniform Sector Dual and Quad Serial Flash

Figure14a. Quad I/O Fast Read Sequence Diagram (M5-4= (1, 0))



Note: The device default is in 24-bit address mode. For 4-byte mode, the address length becomes 32-bit.

Quad I/O Fast Read with "8/16/32/64-Byte Wrap Around" in Standard SPI mode

The Quad I/O Fast Read command can be used to access a specific portion within a page by issuing "Set Burst with Wrap" (77H) commands prior to EBH. The "Set Burst with Wrap" (77H) command can either enable or disable the "Wrap Around" feature for the following EBH commands. When "Wrap Around" is enabled, the data being accessed can be limited to either an 8/16/32/64-byte section of a 256-byte page. The output data starts at the initial address specified in the command, once it reaches the ending boundary of the 8/16/32/64-byte section, the output will wrap around the beginning boundary automatically until CS# is pulled high to terminate the command.

The Burst with Wrap feature allows applications that use cache to quickly fetch a critical address and then fill the cache afterwards within a fixed length (8/16/32/64-byte) of data without issuing multiple read commands. The "Set Burst with Wrap" command allows three "Wrap Bits" W6-W4 to be set. The W4 bit is used to enable or disable the "Wrap Around" operation while W6-W5 is used to specify the length of the wrap around section within a page.

Quad I/O Fast Read (EBH) in QPI mode

The Quad I/O Fast Read command is also supported in QPI mode. See Figure14b. In QPI mode, the number of dummy clocks is configured by the "Set Read Parameters (C0H)" command to accommodate a wide range application with different needs for either maximum Fast Read frequency or minimum data access latency. Depending on the Read Parameter Bits P[5:4] setting, the number of dummy clocks can be configured as either 4/6/8/8. In QPI mode, the "Continuous Read Mode" bits M7-M0 are also considered as dummy clocks. "Continuous Read Mode" feature is also available in QPI mode for Quad I/O Fast Read command. "Wrap Around" feature is not available in QPI mode, a dedicated "Burst Read with Wrap" (0CH) command must be used.

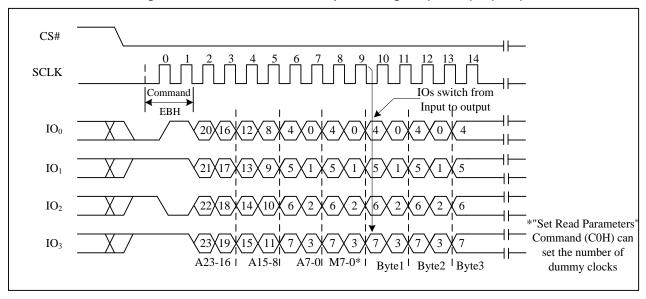


Figure14b. Quad I/O Fast Read Sequence Diagram (M5-4= (1, 0) QPI)

Note: The device default is in 24-bit address mode. For 4-byte mode, the address length becomes 32-bit.

7.14. Quad I/O Word Fast Read (E7H)

The Quad I/O Word Fast Read command is similar to the Quad I/O Fast Read command except that the lowest address bit (A0) must equal 0 and only 2-dummy clock. The command sequence is shown in followed Figure 15. The first byte addressed can be at any location. The address is automatically incremented to the next higher address after each byte of data is shifted out. The Quad Enable bit (QE) of Status Register (S9) must be set to enable for the Quad I/O Word Fast read command.

Quad I/O Word Fast Read with "Continuous Read Mode"

The Quad I/O Word Fast Read command can further reduce command overhead through setting the "Continuous Read Mode" bits (M7-0) after the input 3-byte address (A23-A0) or a 4-byte address (A31-A0). If the "Continuous Read Mode" bits (M5-4) = (1, 0), then the next Quad I/O Word Fast Read command (after CS# is raised and then lowered) does not require the E7H command code. The command sequence is shown in followed Figure 15. If the "Continuous Read Mode" bits (M5-4) do not equal to (1, 0), the next command requires the first E7H command code, thus returning to normal operation. A "Continuous Read Mode" Reset command can be used to reset (M5-4) before issuing normal command.

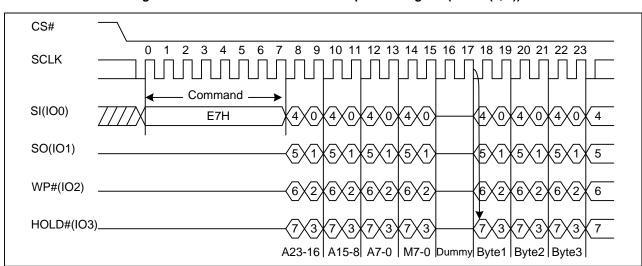


Figure15. Quad I/O Word Fast Read Sequence Diagram (M5-4≠ (1, 0))

Note: The device default is in 24-bit address mode. For 4-byte mode, the address length becomes 32-bit.

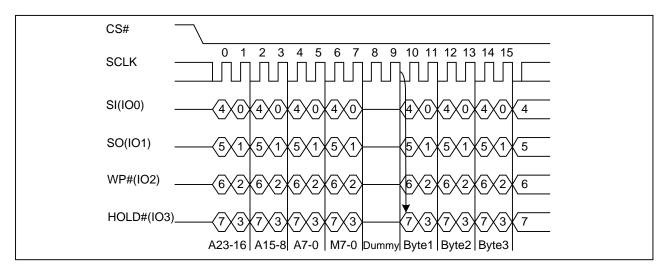


Figure15a. Quad I/O Word Fast Read Sequence Diagram (M5-4= (1, 0))

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Quad I/O Word Fast Read with "8/16/32/64-Byte Wrap Around" in Standard SPI mode

The Quad I/O Word Fast Read command can be used to access a specific portion within a page by issuing "Set Burst with Wrap" (77H) commands prior to E7H. The "Set Burst with Wrap" (77H) command can either enable or disable the "Wrap Around" feature for the following E7H commands. When "Wrap Around" is enabled, the data being accessed can be limited to either an 8/16/32/64-byte section of a 256-byte page. The output data starts at the initial address specified in the command, once it reaches the ending boundary of the 8/16/32/64-byte section, the output will wrap around the beginning boundary automatically until CS# is pulled high to terminate the command.

The Burst with Wrap feature allows applications that use cache to quickly fetch a critical address and then fill the cache afterwards within a fixed length (8/16/32/64-byte) of data without issuing multiple read commands. The "Set Burst with Wrap" command allows three "Wrap Bits" W6-W4 to be set. The W4 bit is used to enable or disable the "Wrap Around" operation while W6-W5 is used to specify the length of the wrap around section within a page.

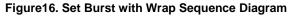
7.15. Set Burst with Wrap (77H)

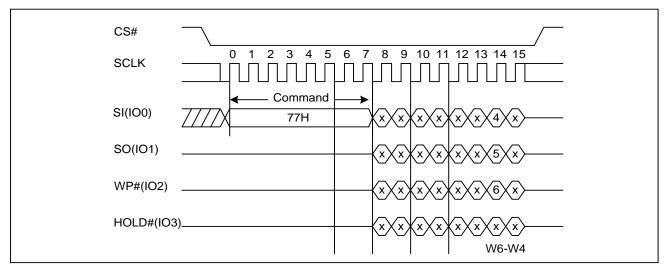
The Set Burst with Wrap command is used in conjunction with "Quad I/O Fast Read" and "Quad I/O Word Fast Read" command to access a fixed length of 8/16/32/64-byte section within a 256-byte page, in standard SPI mode.

The Set Burst with Wrap command sequence: CS# goes low \rightarrow Send Set Burst with Wrap command \rightarrow Send 24 dummy bits \rightarrow Send 8 bits "Wrap bits" \rightarrow CS# goes high.

	W4	l=0	W4=1 (default)		
W6,W5	Wrap Around	Wrap Length	Wrap Around	Wrap Length	
0, 0	Yes	8-byte	No	N/A	
0, 1	Yes	16-byte	No	N/A	
1, 0	Yes	32-byte	No	N/A	
1, 1	Yes	64-byte	No	N/A	

If the W6-W4 bits are set by the Set Burst with Wrap command, all the following "Quad I/O Fast Read" and "Quad I/O Word Fast Read" command will use the W6-W4 setting to access the 8/16/32/64-byte section within any page. To exit the "Wrap Around" function and return to normal read operation, another Set Burst with Wrap command should be issued to set W4=1. In QPI mode, the "Burst Read with Wrap (0CH)" command should be used to perform the Read Operation with "Wrap Around" feature. The Wrap Length set by W5-W6 in Standard SPI mode is still valid in QPI mode and can also be re-configured by "Set Read Parameters (C0H) command.





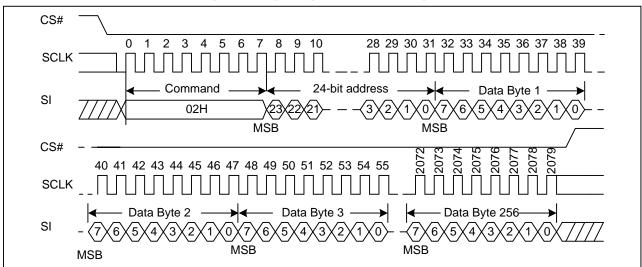
7.16. Page Program (PP) (02H)

The Page Program (PP) command is for programming the memory. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit before sending the Page Program command.

The Page Program (PP) command is entered by driving CS# Low, followed by the command code, three address bytes and at least one data byte on SI. If the 8 least significant address bits (A7-A0) are not all zero, all transmitted data that goes beyond the end of the current page are programmed from the start address of the same page (from the address whose 8 least significant bits (A7-A0) are all zero). CS# must be driven low for the entire duration of the sequence. The Page Program command sequence: CS# goes low \rightarrow sending Page Program command \rightarrow 3-byte address or 4-byte address on SI \rightarrow at least 1 byte data on SI \rightarrow CS# goes high. The command sequence is shown in Figure 17. If more than 256 bytes are sent to the device, previously latched data are discarded and the last 256 data bytes are guaranteed to be programmed correctly within the same page. If less than 256 data bytes are sent to device, they are correctly programmed at the requested addresses without having any effects on the other bytes of the same page. CS# must be driven high after the eighth bit of the last data byte has been latched in; otherwise the Page Program (PP) command is not executed.

As soon as CS# is driven high, the self-timed Page Program cycle (whose duration is t_{PP}) is initiated. While the Page Program cycle is in progress, the Status Register may be read to check the value of the Write in Progress (WIP) bit. The Write in Progress (WIP) bit is 1 during the self-timed Page Program cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset.

A Page Program (PP) command applied to a page which is protected by the Block Protect (BP4, BP3, BP2, BP1, and BP0) is not executed.

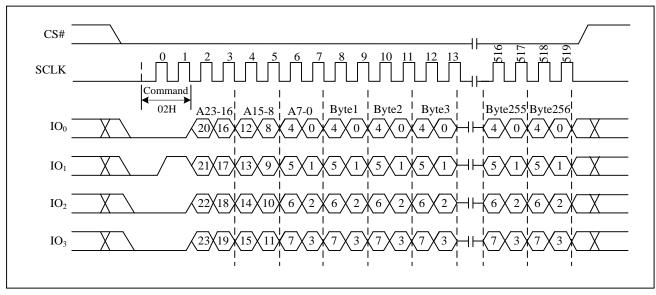






GD25LQ256C





1.8V Uniform Sector GigaDevice Dual and Quad Serial Flash 7.17 Ound Page Program (22H)

7.17. Quad Page Program (32H)

The Quad Page Program command is for programming the memory using four pins: IO0, IO1, IO2, and IO3. To use Quad Page Program the Quad enable in status register Bit9 must be set (QE=1). A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit before sending the Page Program command. The quad Page Program command is entered by driving CS# Low, followed by the command code (32H), three or four address bytes and at least one data byte on IO pins.

The command sequence is shown in Figure 18. If more than 256 bytes are sent to the device, previously latched data are discarded and the last 256 data bytes are guaranteed to be programmed correctly within the same page. If less than 256 data bytes are sent to device, they are correctly programmed at the requested addresses without having any effects on the other bytes of the same page. CS# must be driven high after the eighth bit of the last data byte has been latched in; otherwise the Quad Page Program (PP) command is not executed.

As soon as CS# is driven high, the self-timed Quad Page Program cycle (whose duration is t_{PP}) is initiated. While the Quad Page Program cycle is in progress, the Status Register may be read to check the value of the Write In Progress (WIP) bit. The Write in Progress (WIP) bit is 1 during the self-timed Quad Page Program cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset.

A Quad Page Program command applied to a page which is protected by the Block Protect (BP4, BP3, BP2, BP1, and BP0) is not executed.

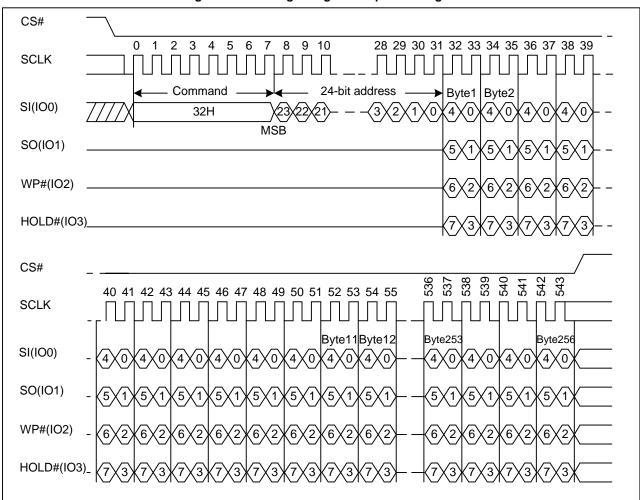


Figure18.Quad Page Program Sequence Diagram

Note: The device default is in 24-bit address mode. For 4-byte mode, the address length becomes 32-bit.

7.18. Sector Erase (SE) (20H)

The Sector Erase (SE) command is erased the all data of the chosen sector. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit. The Sector Erase (SE) command is entered by driving CS# low, followed by the command code, and 3- byte address or 4-byte address on SI. Any address inside the sector is a valid address for the Sector Erase (SE) command. CS# must be driven low for the entire duration of the sequence.

The Sector Erase command sequence: CS# goes low \rightarrow sending Sector Erase command \rightarrow 3-byte address or 4-byte address on SI \rightarrow CS# goes high. The command sequence is shown in Figure19. CS# must be driven high after the eighth bit of the last address byte has been latched in; otherwise the Sector Erase (SE) command is not executed. As soon as CS# is driven high, the self-timed Sector Erase cycle (whose duration is t_{SE}) is initiated. While the Sector Erase cycle is in progress, the Status Register may be read to check the value of the Write in Progress (WIP) bit. The Write in Progress (WIP) bit is 1 during the self-timed Sector Erase cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset. A Sector Erase (SE) command applied to a sector which is protected by the Block Protect (BP4, BP3, BP2, BP1, and BP0) bit (see Table1&1a) is not executed.

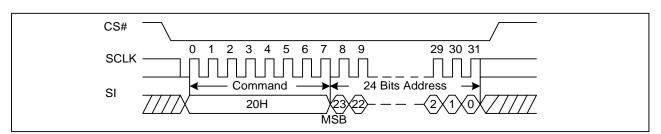
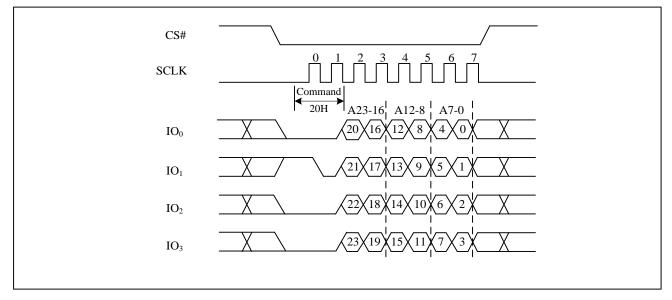


Figure19. Sector Erase Sequence Diagram

Note: The device default is in 24-bit address mode. For 4-byte mode, the address length becomes 32-bit.

Figure19a. Sector Erase Sequence Diagram (QPI)

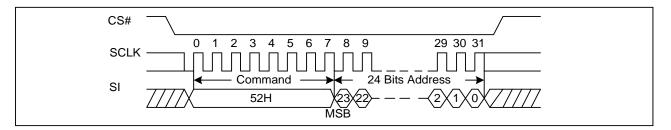


1.8V Uniform Sector GigaDevice Dual and Quad Serial Flash 7.19. 32KB Block Erase (BE) (52H)

The 32KB Block Erase (BE) command is erased the all data of the chosen block. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit. The 32KB Block Erase (BE) command is entered by driving CS# low, followed by the command code, and 3-byte address or 4-byte address on SI. Any address inside the block is a valid address for the 32KB Block Erase (BE) command. CS# must be driven low for the entire duration of the sequence.

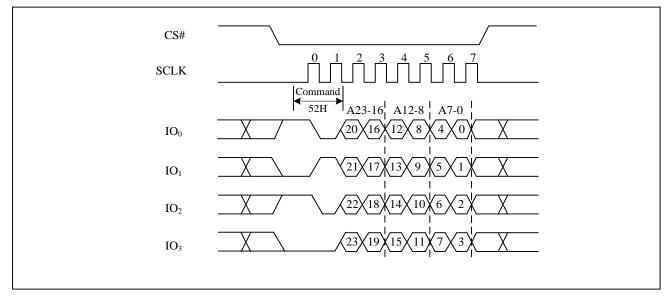
The 32KB Block Erase command sequence: CS# goes low \rightarrow sending 32KB Block Erase command \rightarrow 3-byte address or 4-byte address on SI \rightarrow CS# goes high. The command sequence is shown in Figure20. CS# must be driven high after the eighth bit of the last address byte has been latched in; otherwise the 32KB Block Erase (BE) command is not executed. As soon as CS# is driven high, the self-timed Block Erase cycle (whose duration is t_{SE}) is initiated. While the Block Erase cycle is in progress, the Status Register may be read to check the value of the Write in Progress (WIP) bit. The Write in Progress (WIP) bit is 1 during the self-timed Block Erase cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset. A 32KB Block Erase (BE) command applied to a block which is protected by the Block Protect (BP4, BP3, BP2, BP1, and BP0) bits (see Table1&1a) is not executed.





Note: The device default is in 24-bit address mode. For 4-byte mode, the address length becomes 32-bit.

Figure20a. 32KB Block Erase Sequence Diagram (QPI)

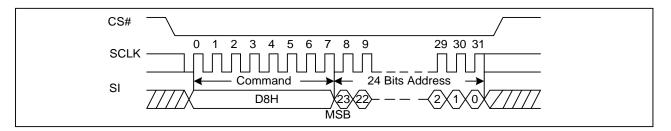


1.8V Uniform Sector <u>GigaDevice</u> Dual and Quad Serial Flash 7.20. 64KB Block Erase (BE) (D8H)

The 64KB Block Erase (BE) command is erased the all data of the chosen block. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit. The 64KB Block Erase (BE) command is entered by driving CS# low, followed by the command code, and 3-byte address or 4-byte address on SI. Any address inside the block is a valid address for the 64KB Block Erase (BE) command. CS# must be driven low for the entire duration of the sequence.

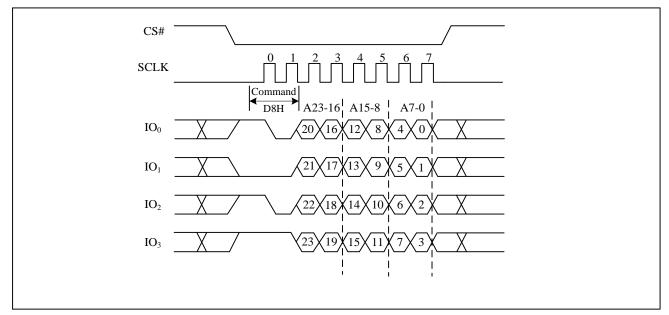
The 64KB Block Erase command sequence: CS# goes low \rightarrow sending 64KB Block Erase command \rightarrow 3-byte address or 4-byte address on SI \rightarrow CS# goes high. The command sequence is shown in Figure21. CS# must be driven high after the eighth bit of the last address byte has been latched in; otherwise the 64KB Block Erase (BE) command is not executed. As soon as CS# is driven high, the self-timed Block Erase cycle (whose duration is t_{SE}) is initiated. While the Block Erase cycle is in progress, the Status Register may be read to check the value of the Write in Progress (WIP) bit. The Write in Progress (WIP) bit is 1 during the self-timed Block Erase cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset. A 64KB Block Erase (BE) command applied to a block which is protected by the Block Protect (BP4, BP3, BP2, BP1, and BP0) bits (see Table1&1a) is not executed.





Note: The device default is in 24-bit address mode. For 4-byte mode, the address length becomes 32-bit.

Figure21a. 64KB Block Erase Sequence Diagram (QPI)



1.8V Uniform Sector GigaDevice Dual and Quad Serial Flash 7.21. Chip Erase (CE) (60/C7H)

The Chip Erase (CE) command is erased the all data of the chip. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit .The Chip Erase (CE) command is entered by driving CS# Low, followed by the command code on Serial Data Input (SI). CS# must be driven Low for the entire duration of the sequence.

The Chip Erase command sequence: CS# goes low \rightarrow sending Chip Erase command \rightarrow CS# goes high. The command sequence is shown in Figure22. CS# must be driven high after the eighth bit of the command code has been latched in; otherwise the Chip Erase command is not executed. As soon as CS# is driven high, the self-timed Chip Erase cycle (whose duration is t_{CE}) is initiated. While the Chip Erase cycle is in progress, the Status Register may be read to check the value of the Write in Progress (WIP) bit. The Write in Progress (WIP) bit is 1 during the self-timed Chip Erase cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset. The Chip Erase (CE) command is executed only if all Block Protect (BP2, BP1, and BP0) bits are 0. The Chip Erase (CE) command is gnored if one or more sectors are protected.

Figure22. Chip Erase Sequence Diagram

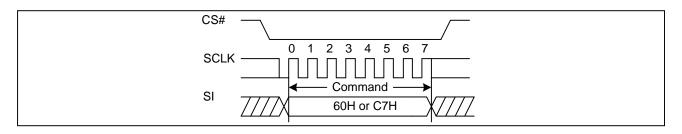
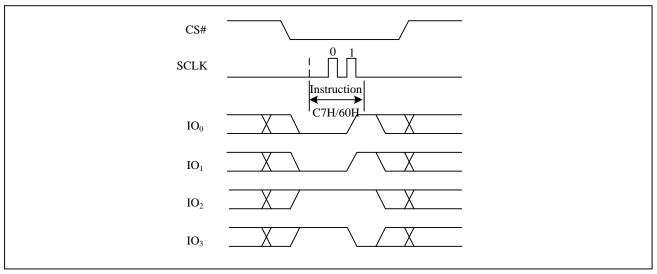


Figure22a. Chip Erase Sequence Diagram (QPI)



7.22. Deep Power-Down (DP) (B9H)

Executing the Deep Power-Down (DP) command is the only way to put the device in the lowest consumption mode (the Deep Power-Down Mode). It can also be used as an extra software protection mechanism, while the device is not in active use, since in this mode, the device ignores all Write, Program and Erase commands. Driving CS# high deselects the device, and puts the device in the Standby Mode (if there is no internal cycle currently in progress). But this mode is not the Deep Power-Down Mode. The Deep Power-Down Mode can only be entered by executing the Deep Power-Down (DP) command. Once the device has entered the Deep Power-Down Mode, all commands are ignored except the Release from Deep Power-Down and Read Device ID (RDI) command. This releases the device from this mode. The Release from Deep Power-Down and Read Device ID (RDI) command also allows the Device ID of the device to be output on SO.

The Deep Power-Down Mode automatically stops at Power-Down, and the device always Power-Up in the Standby Mode. The Deep Power-Down (DP) command is entered by driving CS# low, followed by the command code on SI. CS# must be driven low for the entire duration of the sequence.

The Deep Power-Down command sequence: CS# goes low \rightarrow sending Deep Power-Down command \rightarrow CS# goes high. The command sequence is shown in Figure23. CS# must be driven high after the eighth bit of the command code has been latched in; otherwise the Deep Power-Down (DP) command is not executed. As soon as CS# is driven high, it requires a delay of toP before the supply current is reduced to I_{CC2} and the Deep Power-Down Mode is entered. Any Deep Power-Down (DP) command, while an Erase, Program or Write cycle is in progress, is rejected without having any effects on the cycle that is in progress.

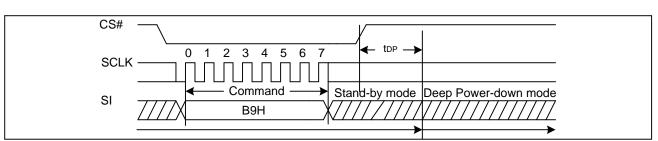
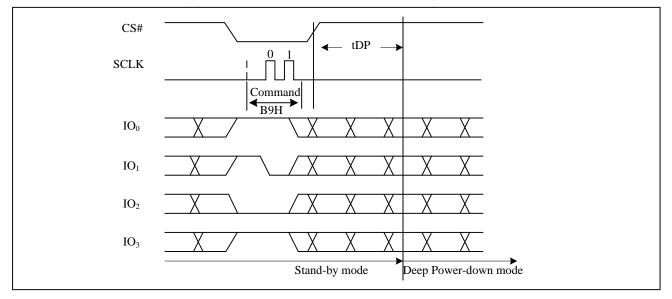


Figure23. Deep Power-Down Sequence Diagram





7.23. Release from Deep Power-Down and Read Device ID (RDI) (ABH)

The Release from Power-Down and Read Device ID command is a multi-purpose command. It can be used to release the device from the Power-Down state or obtain the devices electronic identification (ID) number.

To release the device from the Power-Down state, the command is issued by driving the CS# pin low, shifting the instruction code "ABH" and driving CS# high as shown in Figure24. Release from Power-Down will take the time duration of t_{RES1} (See AC Characteristics) before the device will resume normal operation and other command are accepted. The CS# pin must remain high during the t_{RES1} time duration.

When used only to obtain the Device ID while not in the Power-Down state, the command is initiated by driving the CS# pin low and shifting the instruction code "ABH" followed by 3-dummy byte. The Device ID bits are then shifted out on the falling edge of SCLK with most significant bit (MSB) first as shown in Figure24. The Device ID value for the GD25LQ256C is listed in Manufacturer and Device Identification table. The Device ID can be read continuously. The command is completed by driving CS# high.

When used to release the device from the Power-Down state and obtain the Device ID, the command is the same as previously described, and shown in Figure25, except that after CS# is driven high it must remain high for a time duration of t_{RES2} (See AC Characteristics). After this time duration the device will resume normal operation and other command will be accepted. If the Release from Power-Down / Device ID command is issued while an Erase, Program or Write cycle is in process (when WIP equal 1) the command is ignored and will not have any effects on the current cycle.



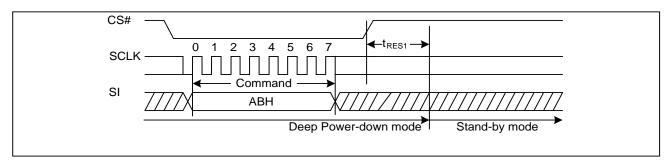
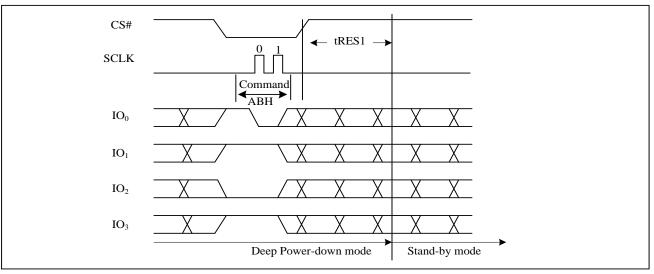
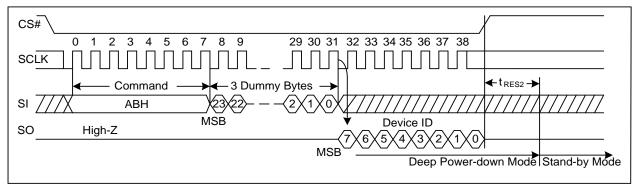


Figure24a. Release Power-Down Sequence Diagram (QPI)



GD25LQ256C

Figure25. Release Power-Down/Read Device ID Sequence Diagram



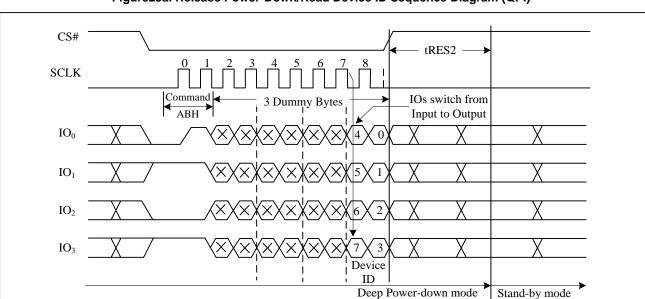


Figure25a. Release Power-Down/Read Device ID Sequence Diagram (QPI)

7.24. Read Manufacture ID/ Device ID (REMS) (90H)

The Read Manufacturer/Device ID command is an alternative to the Release from Power-Down / Device ID command that provides both the JEDEC assigned Manufacturer ID and the specific Device ID.

The command is initiated by driving the CS# pin low and shifting the command code "90H" followed by a 24-bit address (A23-A0) of 000000H. After which, the Manufacturer ID and the Device ID are shifted out on the falling edge of SCLK with most significant bit (MSB) first as shown in Figure 26. If the 24-bit address is initially set to 000001H, the Device ID will be read first.

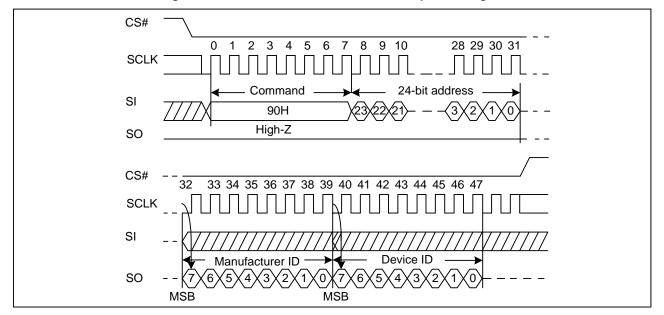
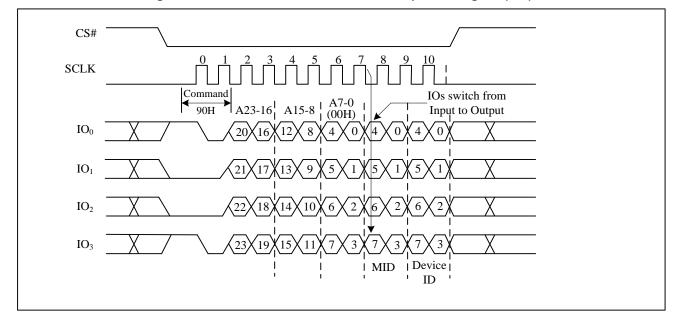


Figure26. Read Manufacture ID/ Device ID Sequence Diagram

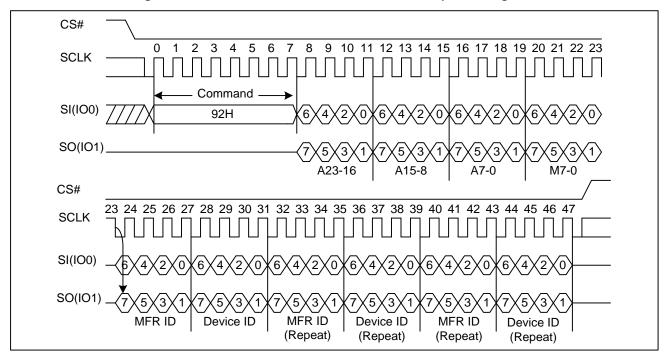
Figure26a. Read Manufacture ID/ Device ID Sequence Diagram (QPI)



7.25. Read Manufacture ID/ Device ID Dual I/O (92H)

The Read Manufacturer/Device ID Dual I/O command is an alternative to the Release from Power-Down / Device ID command that provides both the JEDEC assigned Manufacturer ID and the specific Device ID by dual I/O.

The command is initiated by driving the CS# pin low and shifting the command code "92H" followed by a 24-bit address (A23-A0) of 000000H. After which, the Manufacturer ID and the Device ID are shifted out on the falling edge of SCLK with most significant bit (MSB) first as shown in Figure27. If the 24-bit address is initially set to 000001H, the Device ID will be read first.





7.26. Read Manufacture ID/ Device ID Quad I/O (94H)

The Read Manufacturer/Device ID Quad I/O command is an alternative to the Release from Power-Down / Device ID command that provides both the JEDEC assigned Manufacturer ID and the specific Device ID by quad I/O.

The command is initiated by driving the CS# pin low and shifting the command code "94H" followed by a 24-bit address (A23-A0) of 000000H. After which, the Manufacturer ID and the Device ID are shifted out on the falling edge of SCLK with most significant bit (MSB) first as shown in Figure 28. If the 24-bit address is initially set to 000001H, the Device ID will be read first.

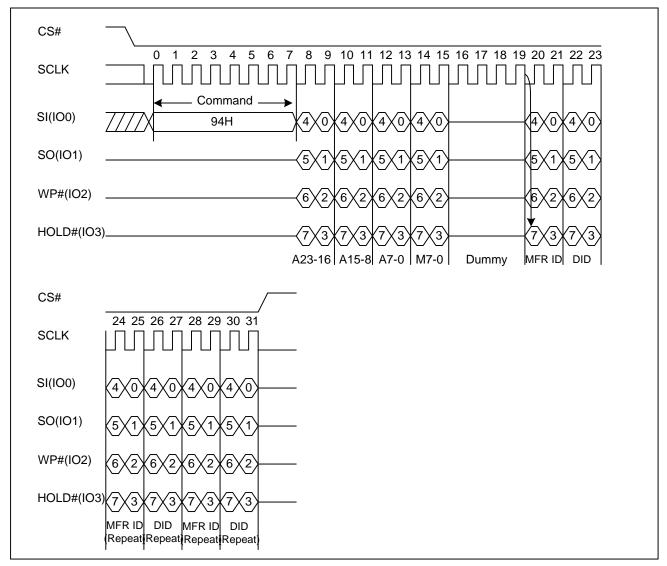


Figure 28. Read Manufacture ID/ Device ID Quad I/O Sequence Diagram

1.8V Uniform Sector <u>GigaDevice</u> Dual and Quad Serial Flash 7.27. Read Identification (RDID) (9FH)

The Read Identification (RDID) command allows the 8-bit manufacturer identification to be read, followed by two bytes of device identification. The device identification indicates the memory type in the first byte, and the memory capacity of the device in the second byte. The Read Identification (RDID) command while an Erase or Program cycle is in progress, is not decoded, and has no effect on the cycle that is in progress. The Read Identification (RDID) command should not be issued while the device is in Deep Power-Down Mode.

The device is first selected by driving CS# to low. Then, the 8-bit command code for the command is shifted in. This is followed by the 24-bit device identification, stored in the memory, being shifted out on Serial Data Output, each bit being shifted out during the falling edge of Serial Clock. The command sequence is shown in Figure29. The Read Identification (RDID) command is terminated by driving CS# to high at any time during data output. When CS# is driven high, the device is put in the Standby Mode. Once in the Standby Mode, the device waits to be selected, so that it can receive, decode and execute commands.

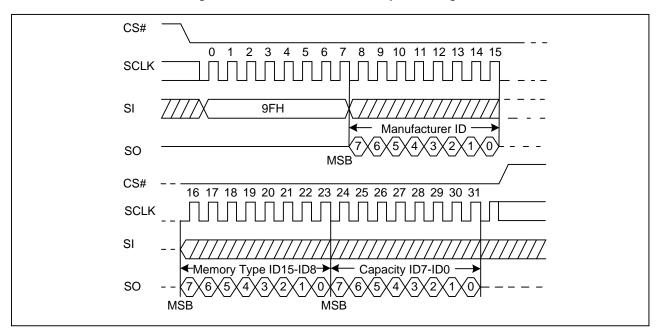
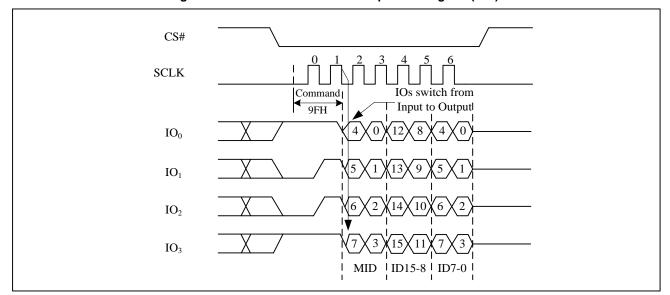
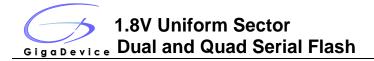


Figure29. Read Identification ID Sequence Diagram

Figure29a. Read Identification ID Sequence Diagram (QPI)





7.28. Program/Erase Suspend (PES) (75H)

The Program/Erase Suspend command "75H", allows the system to interrupt a page program or sector/block erase operation and then read data from any other sector or block. The Write Status Register command (01H) and Erase Security Registers (44H, 42H) and Erase commands (20H, 52H, D8H, C7H, 60H) and Page Program command are not allowed during Program/Erase suspend. Program/Erase Suspend is valid only during the page program or sector/block erase operation. A maximum of time of "tsus" (See AC Characteristics) is required to suspend the program/erase operation.

The Program/Erase Suspend command will be accepted by the device only if the SUS2/SUS1 bit in the Status Register equal to 0 and WIP bit equal to 1 while a Page Program or a Sector or Block Erase operation is on-going. If the SUS2/SUS1 bit equal to 1 or WIP bit equal to 0, the Suspend command will be ignored by the device. The WIP bit will be cleared from 1 to 0 within "tsus" and the SUS2/SUS1 bit will be set from 0 to 1 immediately after Program/Erase Suspend. A power-off during the suspend period will reset the device and release the suspend state. The command sequence is show in Figure30.

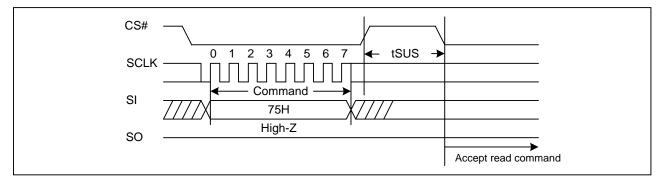
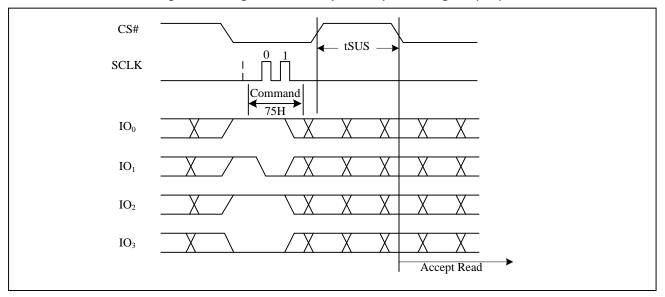


Figure30. Program/Erase Suspend Sequence Diagram

Figure30a. Program/Erase Suspend Sequence Diagram (QPI)

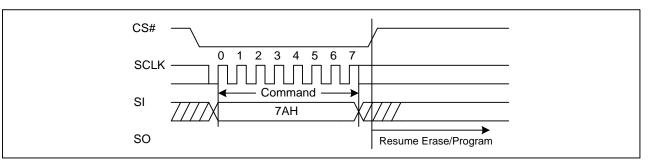




7.29. Program/Erase Resume (PER) (7AH)

The Program/Erase Resume command must be written to resume the program or sector/block erase operation after a Program/Erase Suspend command. The Program/Erase command will be accepted by the device only if the SUS2/SUS1 bit equal to 1 and the WIP bit equal to 0. After issued the SUS2/SUS1 bit in the status register will be cleared from 1 to 0 immediately, the WIP bit will be set from 0 to 1 within 200ns and the Sector or Block will complete the erase operation or the page will complete the program operation. The Program/Erase Resume command will be ignored unless a Program/Erase Suspend is active. The command sequence is show in Figure31.





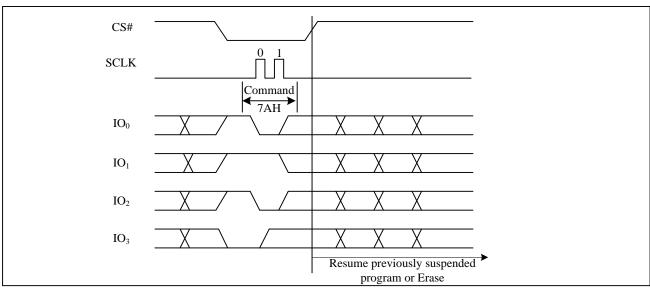


Figure31a. Program/Erase Resume Sequence Diagram (QPI)



7.30. Erase Security Registers (44H)

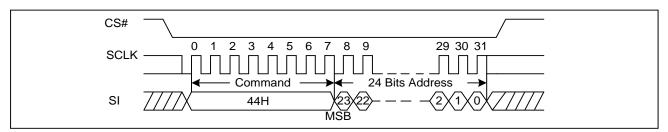
The GD25LQ256C provides two 512-byte Security Registers which can be erased and programmed individually. These registers may be used by the system manufacturers to store security and other important information separately from the main memory array.

The Erase Security Registers command is similar to Sector/Block Erase command. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit.

The Erase Security Registers command sequence: CS# goes low \rightarrow sending Erase Security Registers command \rightarrow CS# goes high. The command sequence is shown in Figure32. CS# must be driven high after the eighth bit of the command code has been latched in; otherwise the Erase Security Registers command is not executed. As soon as CS# is driven high, the self-timed Erase Security Registers cycle (whose duration is tsE) is initiated. While the Erase Security Registers cycle is in progress, the Status Register may be read to check the value of the Write in Progress (WIP) bit. The Write in Progress (WIP) bit is 1 during the self-timed Erase Security Registers cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset. The Security Registers Lock Bit (LB2-3) in the Status Register can be used to OTP protect the security registers. Once the LB bit is set to 1, the Security Registers will be permanently locked; the Erase Security Registers command will be ignored.

Address	A23-16	A15-12	A11-9	A8-0
Security Register #2	00H	0010	000	Do not care
Security Register #3	00H	0011	000	Do not care





7.31. Program Security Registers (42H)

The Program Security Registers command is similar to the Page Program command. It allows from 1 to 512 bytes Security Registers data to be programmed. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit before sending the Program Security Registers command. The Program Security Registers command is entered by driving CS# Low, followed by the command code (42H), three address bytes and at least one data byte on SI. As soon as CS# is driven high, the self-timed Program Security Registers cycle (whose duration is t_{PP}) is initiated. While the Program Security Registers cycle is in progress, the Status Register may be read to check the value of the Write in Progress (WIP) bit. The Write in Progress (WIP) bit is 1 during the self-timed Program Security Registers cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset.

If the Security Registers Lock Bit (LB2-3) is set to 1, the Security Registers will be permanently locked. Program Security Registers command will be ignored.

Address	A23-16	A15-12	A11-9	A8-0
Security Register #2	00H	0010	000	Do not care
Security Register #3	00H	0011	000	Do not care

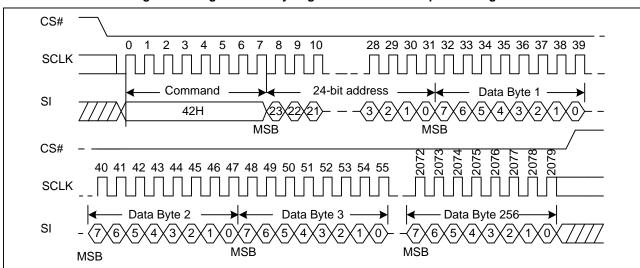


Figure 33. Program Security Registers command Sequence Diagram

Read Security Registers (48H) 7.32.

The Read Security Registers command is similar to Fast Read command. The command i is followed by a 3-byte address (A23-A0) and a dummy byte, each bit being latched-in during the rising edge of SCLK. Then the memory content, at that address, is shifted out on SO, each bit being shifted out, at a Max frequency fc, during the falling edge of SCLK. The first byte addressed can be at any location. The address is automatically incremented to the next higher address after each byte of data is shifted out. Once the A8-A0 address reaches the last byte of the register (Byte 1FFH), it will reset to 000H, the command is completed by driving CS# high.

Address	A23-16	A15-12	A11-9	A8-0
Security Register #2	00H	0010	000	Byte Address
Security Register #3	00H	0011	000	Byte Address

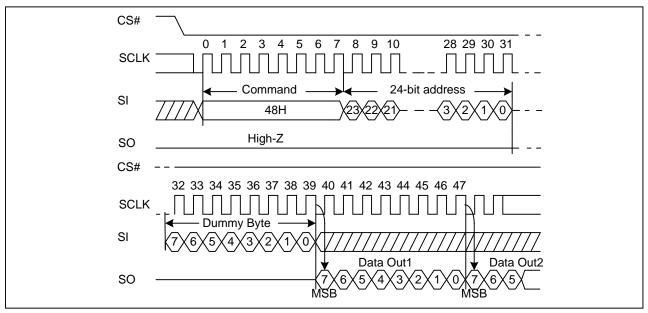


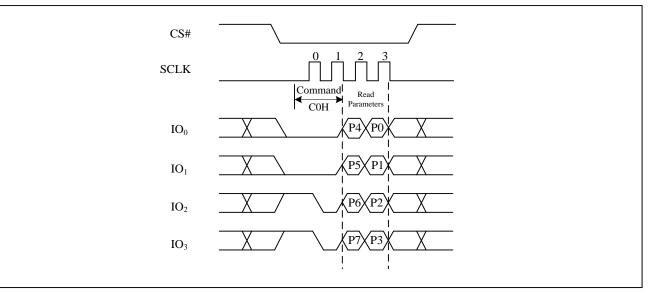
Figure34. Read Security Registers command Sequence Diagram

7.33. Set Read Parameters (C0H)

In QPI mode the "Set Read Parameters (C0H)" command can be used to configure the number of dummy clocks for "Fast Read (0BH)", "Quad I/O Fast Read (EBH)", "Burst Read with Wrap (0CH)", "Burst Read with Wrap for Lower 128Mb (8CH)" and "Burst Read with Wrap For Higher 128Mb (8DH)" command, and to configure the number of bytes of "Wrap Length" for the "Burst Read with Wrap (0CH)" command. The "Wrap Length" is set by W5-6 bit in the "Set Burst with Wrap (77H)" command. This setting will remain unchanged when the device is switched from Standard SPI mode to QPI mode.

P5-P4	Dummy Clocks	Maximum Read Freq.	P1-P0	Wrap Length
0 0	4	80MHz	0 0	8-byte
0 1	6	108MHz	0 1	16-byte
10	8	120MHz	1 0	32-byte
11	8	120MHz	11	64-byte







7.34. Burst Read with Wrap (0CH)

The "Burst Read with Wrap (0CH)" command provides an alternative way to perform the read operation with "Wrap Around" in QPI mode. This command is similar to the "Fast Read (0BH)" command in QPI mode, except the addressing of the read operation will "Wrap Around" to the beginning boundary of the "Wrap Around" once the ending boundary is reached. The "Wrap Length" and the number of dummy clocks can be configured by the "Set Read Parameters (C0H)" command.

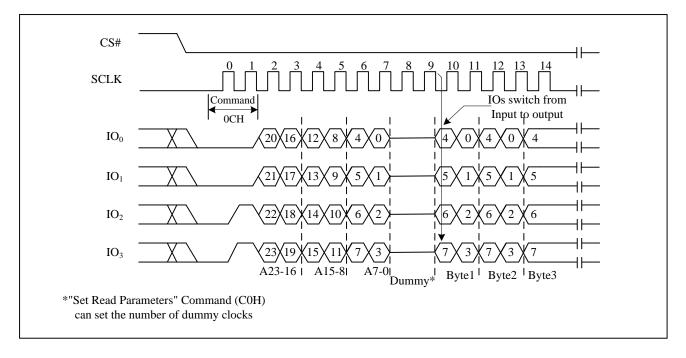
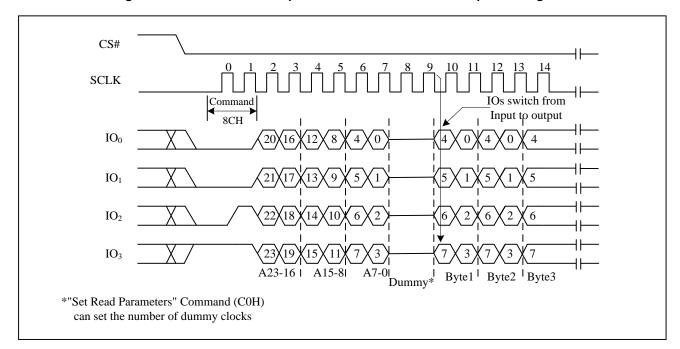


Figure36. Burst Read with Wrap command Sequence Diagram

7.35. Burst Read with Wrap for Lower 128Mb (8CH)

The "Burst Read with Wrap for Lower 128Mb (8CH)" command provides an alternative way to perform the read operation with "Wrap Around" in QPI mode. This command is similar to the "Fast Read (0BH)" command in QPI mode, except the addressing of the read operation will "Wrap Around" to the beginning boundary of the "Wrap Around" once the ending boundary is reached. The "Wrap Length" and the number of dummy clocks can be configured by the "Set Read Parameters (C0H)" command. The "Burst Read with Wrap for Lower 128Mb (8CH)" command will read out the memory content from 000000H to 0FFFFFH.

The "Burst Read with Wrap for Lower 128Mb (8CH)" command sequence: CS# goes low \rightarrow sending The "Burst Read with Wrap for Lower 128Mb (8CH)" command \rightarrow sending 3-byte address (A23-A0, The A24 default value is 0) \rightarrow sending dummy byte \rightarrow then data out.



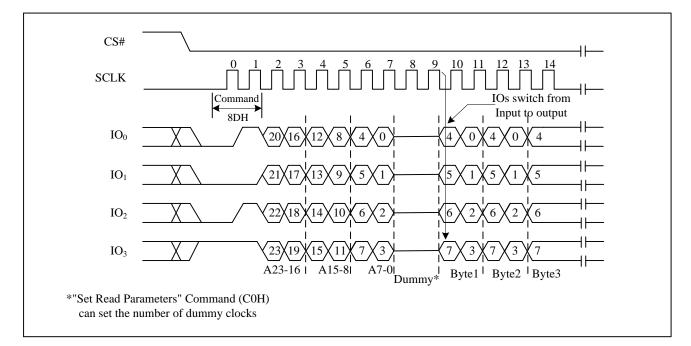




7.36. Burst Read with Wrap for Higher 128Mb (8DH)

The "Burst Read with Wrap for Higher 128Mb (8DH)" command provides an alternative way to perform the read operation with "Wrap Around" in QPI mode. This command is similar to the "Fast Read (0BH)" command in QPI mode, except the addressing of the read operation will "Wrap Around" to the beginning boundary of the "Wrap Around" once the ending boundary is reached. The "Wrap Length" and the number of dummy clocks can be configured by the "Set Read Parameters (C0H)" command. The "Burst Read with Wrap for higher 128Mb (8DH)" command will read out the memory content from 1000000H to 1FFFFFH.

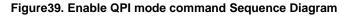
The "Burst Read with Wrap for Higher 128Mb (8DH)" command sequence: CS# goes low \rightarrow sending The "Burst Read with Wrap for Higher 128Mb (8DH)" command \rightarrow sending 3-byte address (A23-A0, The A24 default value is 1) \rightarrow sending dummy byte \rightarrow then data out.

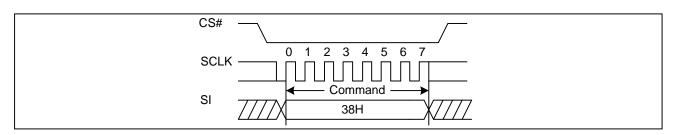




7.37. Enable QPI (38H)

The device support both Standard/Dual/Quad SPI and QPI mode. The "Enable QPI (38H)" command can switch the device from SPI mode to QPI mode. See the command Table 2a for all support QPI commands. In order to switch the device to QPI mode, the Quad Enable (QE) bit in Status Register-1 must be set to 1 first, and "Enable QPI (38H)" command must be issued. If the QE bit is 0, the "Enable QPI (38H)" command will be ignored and the device will remain in SPI mode. When the device is switched from SPI mode to QPI mode, the existing Write Enable Latch and Program/Erase Suspend status, and the Wrap Length setting will remain unchanged.





7.38. Disable QPI (FFH)

To exit the QPI mode and return to Standard/Dual/Quad SPI mode, the "Disable QPI (FFH)" command must be issued. When the device is switched from QPI mode to SPI mode, the existing Write Enable Latch and Program/Erase Suspend status, and the Wrap Length setting will remain unchanged.

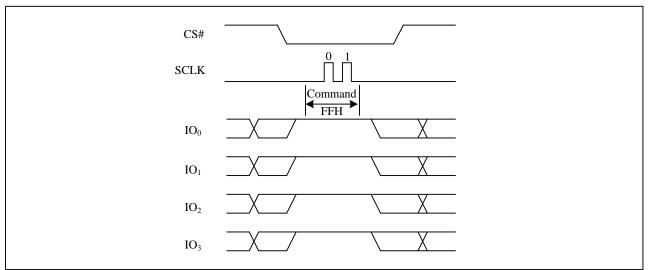


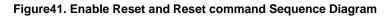
Figure 40. Disable QPI mode command Sequence Diagram



7.39. Enable Reset (66H) and Reset (99H)

If the Reset command is accepted, any on-going internal operation will be terminated and the device will return to its default power-on state and lose all the current volatile settings, such as Volatile Status Register bits, Write Enable Latch status (WEL), Program/Erase Suspend status, Read Parameter setting (P7-P0), Continuous Read Mode bit setting (M7-M0) and Wrap Bit Setting (W6-W4).

The "Enable Reset (66H)" and the "Reset (99H)" commands can be issued in either SPI or QPI mode. The "Reset (99H)" command sequence as follow: CS# goes low \rightarrow Sending Enable Reset command \rightarrow CS# goes high \rightarrow CS# goes low \rightarrow Sending Reset command \rightarrow CS# goes high. Once the Reset command is accepted by the device, the device will take approximately t_{RST} =30us to reset. During this period, no command will be accepted. Data corruption may happen if there is an on-going or suspended internal Erase or Program operation when Reset command sequence is accepted by the device. It is recommended to check the BUSY bit and the SUS bit in Status Register before issuing the Reset command sequence.



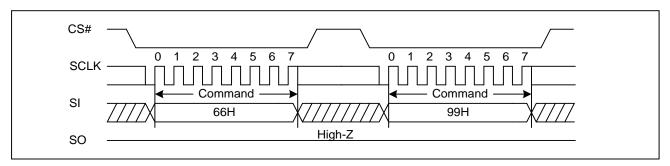
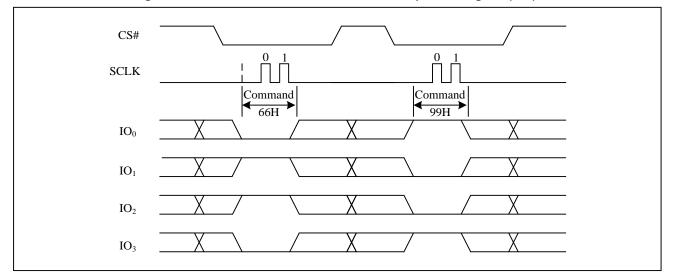


Figure41a. Enable Reset and Reset command Sequence Diagram (QPI)





7.40. Read Serial Flash Discoverable Parameter (5AH)

The Serial Flash Discoverable Parameter (SFDP) standard provides a consistent method of describing the functional and feature capabilities of serial flash devices in a standard set of internal parameter tables. These parameter tables can be interrogated by host system software to enable adjustments needed to accommodate divergent features from multiple vendors. The concept is similar to the one found in the Introduction of JEDEC Standard, JESD68 on CFI. SFDP is a standard of JEDEC Standard No.216.

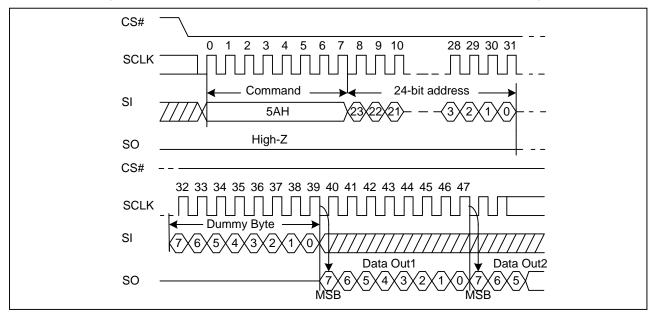
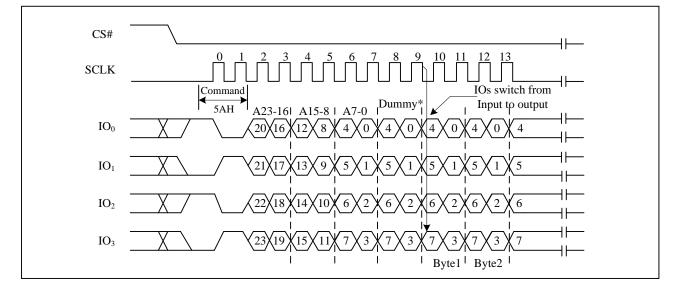


Figure42. Read Serial Flash Discoverable Parameter command Sequence Diagram

Figure42a. Read Serial Flash Discoverable Parameter command Sequence Diagram (QPI)





Description	Comment	Add(H)	DW Add	Data	Data
		(Byte)	(Bit)		
SFDP Signature	Fixed:50444653H	00H	07:00	53H	53H
		01H	15:08	46H	46H
		02H	23:16	44H	44H
		03H	31:24	50H	50H
SFDP Minor Revision Number	Start from 00H	04H	07:00	00H	00H
SFDP Major Revision Number	Start from 01H	05H	15:08	01H	01H
Number of Parameters Headers	Start from 00H	06H	23:16	01H	01H
Unused	Contains 0xFFH and can never be changed	07H	31:24	FFH	FFH
ID number (JEDEC)	00H: It indicates a JEDEC specified header	08H	07:00	00H	00H
Parameter Table Minor Revision Number	Start from 0x00H	09H	15:08	00H	00H
Parameter Table Major Revision Number	Start from 0x01H	0AH	23:16	01H	01H
Parameter Table Length (in double word)	How many DWORDs in the Parameter table	0BH	31:24	09H	09H
Parameter Table Pointer (PTP)	First address of JEDEC Flash	0CH	07:00	30H	30H
	Parameter table	0DH	15:08	00H	00H
		0EH	23:16	00H	00H
Unused	Contains 0xFFH and can never be changed	0FH	31:24	FFH	FFH
ID Number LSB	It is indicates GigaDevice	10H	07:00	C8H	C8H
(GigaDevice Manufacturer ID)	manufacturer ID				
Parameter Table Minor Revision Number	Start from 0x00H	11H	15:08	00H	00H
Parameter Table Major Revision Number	Start from 0x01H	12H	23:16	01H	01H
Parameter Table Length	How many DWORDs in the	13H	31:24	03H	03H
(in double word)	Parameter table				
Parameter Table Pointer (PTP)	First address of GigaDevice Flash	14H	07:00	60H	60H
	Parameter table	15H	15:08	00H	00H
		16H	23:16	00H	00H
Unused	Contains 0xFFH and can never be	17H	31:24	FFH	FFH

Table3. Signature and Parameter Identification Data Values



changed

Table4. Parameter Table (0): JEDEC Flash Parameter T	ables
Table4. Farameter Table (0). JEDEC Flash Farameter 1	anies

Description	Comment	Add(H)	DW Add	Data	Data
		(Byte)	(Bit)		
	00: Reserved; 01: 4KB erase;				
Block/Sector Erase Size	10: Reserved;		01:00	01b	
	11: not support 4KB erase				
Write Granularity	0: 1Byte, 1: 64Byte or larger		02	1b	
Write Enable Instruction	0: Nonvolatile status bit				
Requested for Writing to Volatile	1: Volatile status bit		03	0b	
Status Registers	(BP status register bit)	30H			E5H
	0: Use 50H Opcode,	5011			LOIT
Write Enable Opcode Select for	1: Use 06H Opcode,				
Writing to Volatile Status Registers	Note: If target flash status register is		04	0b	
	Nonvolatile, then bits 3 and 4 must				
	be set to 00b.				
Unused	Contains 111b and can never be		07:05	111b	
Unused	changed		07.00		
4KB Erase Opcode		31H	15:08	20H	20H
(1-1-2) Fast Read	0=Not support, 1=Support		16	1b	
Address Bytes Number used in	00: 3Byte only, 01: 3 or 4Byte,		40.47	0.0	
addressing flash array	10: 4Byte only, 11: Reserved		18:17	00b	
Double Transfer Rate (DTR)	0 Not support 1 Support		10	Oh	
clocking	0=Not support, 1=Support	32H	19	0b	F1H
(1-2-2) Fast Read	0=Not support, 1=Support		20	1b	
(1-4-4) Fast Read	0=Not support, 1=Support		21	1b	
(1-1-4) Fast Read	0=Not support, 1=Support		22	1b	
Unused			23	1b	
Unused		33H	31:24	FFH	FFH
Flash Memory Density		37H:34H	31:00	0FFFFF	FFH
(1-4-4) Fast Read Number of Wait	0 0000b: Wait states (Dummy		04:00	001006	
states	Clocks) not support	2011	04:00	00100b	4411
(1-4-4) Fast Read Number of	000h:Mada Pita pat augast	38H	07.05	0106	44H
Mode Bits	000b:Mode Bits not support		07:05	010b	
(1-4-4) Fast Read Opcode		39H	15:08	EBH	EBH
(1-1-4) Fast Read Number of Wait	0 0000b: Wait states (Dummy		20.16	010006	
states	Clocks) not support	3AH	20:16	01000b	08H
(1-1-4) Fast Read Number of	000b:Mode Bits not support		23:21	000b	



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(1-1.2) Fast Read Number of Mode Bits 0 0000b: Wait states (Dummy Clocks) not support 3CH 04:00 01000b 08H (1-1.2) Fast Read Number of Mode Bits 000b: Mode Bits not support 3DH 15:08 3BH 3BH (1-2.2) Fast Read Number of Mode Bits 0 000b: Wait states (Dummy of Wait states 3DH 15:08 3BH 3BH (1-2.2) Fast Read Number of Mode Bits 0 000b: Mode Bits not support 3EH 20:16 00010b 42H (1-2.2) Fast Read Opcode 3FH 31:24 BBH BBH BBH (1-2.2) Fast Read 0=not support 1=support 40H 04 0b 00 0b Unused 0=not support 1=support 40H 04 1b FEH 000 0b 7:05 111b 111b FEH 0:000b 0:000b 0:000b 0:000b 0:000b 0:0000b 0:0000b 0:000b 0:000b 0:000b 0:000b 0:000b 0:000b 0:000b 0:000b 0:0000b <td< th=""><th>orgabetice</th><th></th><th></th><th></th><th></th><th></th></td<>	orgabetice					
(1-12) Fast Read Number of Mode Bits not support 0000b: Wait states (Dummy Clocks) not support 04:00 01000b 08H (1-12) Fast Read Number of Mode Bits not support 000b: Mode Bits not support 07:05 000b 08H (1-12) Fast Read Number of Mode Bits not support 0000b: Wait states (Dummy Clocks) not support 3EH 20:16 00010b 23:21 010b (1-22) Fast Read Opcode 0000b: Mode Bits not support 3EH 20:16 00010b 23:21 010b 20:16 00000b 23:21 20:16 00000b 23:21 111b 11:24 8EH 23:21 000b 23:21 20:16 0000b 23:21 20:16 00000b 23:21 20:16 0000b 23:21 000b 23:21 000b	Mode Bits					
Wait statesClocks) not support 3CH 04.00 $01000b$ $000b$ (1-1-2) Fast Read Number of Mode Bits000b: Mode Bits not support 3CH 5.08 3BH 3BH (1-2) Fast Read Number of Wait states0000b: Wait states (Dummy Clocks) not support 3CH 5.08 3BH 3BH (1-2) Fast Read Number of Mode Bits000b: Mode Bits not support 3CH 31.24 $B \text{BH}$ 8BH (1-2.2) Fast Read Opcode $0 = not support$ 3FH 31.24 $B \text{BH}$ 8BH (2-2.2) Fast Read Opcode $0 = not support$ 3FH 31.24 $B \text{BH}$ 8BH (2-2.2) Fast Read Opcode $0 = not support$ 3FH 31.24 $B \text{BH}$ 8BH (2-2.2) Fast Read Number Unused $0 = not support$ 3FH 31.24 $B \text{BH}$ 8BH (2-2.2) Fast Read Number Unused $0 0000: Wait states (DummyClocks) not support43 \text{H} 4431.080 \text{AFFH}0 \text{AFFI}(2-2.2) Fast Read Number(2-2.2) Fast Read NumberUnused0 0000: Wait states (DummyClocks) not support4 \text{H} 4431.24F \text{FH}F \text{FH}Unused0 0000: Wait states (DummyClocks) not support4 \text{H} 4431.24F \text{FH}5 \text{FH}(2-2.2) Fast Read Number(Clocks) not support0000: Wait states (DummyClocks) not support4 \text{H} 4431.24F \text{FH}5 \text{FH}(4-4.4) Fast Read Number of Wait(Mode Bits not support4 $	(1-1-4) Fast Read Opcode		3BH	31:24	6BH	6BH
Wait statesClocks) not support $3CH$ 1000 10000 $00H$	(1-1-2) Fast Read Number of	0 0000b: Wait states (Dummy		04.00	01000h	
(1-12) Fast Read Number of Mode Bits 000b: Mode Bits not support 07.05 000b (1-12) Fast Read Opcode 3DH 15.08 3BH 3BH (1-22) Fast Read Number of Mode Bits 0000b: Wait states (Dummy Clocks) not support 3EH 20.16 0001b 42H (1-22) Fast Read Number of Mode Bits 000b: Mode Bits not support 3FH 31.24 BBH BBH (1-22) Fast Read Opcode 0-not support 1=support 40H 000 0b (1-22) Fast Read Opcode 0-not support 1=support 40H 000 0b (1-22) Fast Read Opcode 0-not support 1=support 40H 000 0b (1-22) Fast Read Opcode 0-not support 1=support 40H 15:00 0xFFH 0xFFH (1-22) Fast Read Number 0000b: Wait states (Dummy 45H:44H 15:00 0xFFH 0xFFH (2-22) Fast Read Number 000b: Mode Bits not support 42H 616 0000b 02FH 0xFFH 0xFFH 0xFFH 0xFFH 0xFFH 0xFH 0xFH 0xFFH <td>Wait states</td> <td>Clocks) not support</td> <td>304</td> <td>04.00</td> <td colspan="2"></td>	Wait states	Clocks) not support	304	04.00		
of Mode Bitsrefrefrefref(1-1-2) Fast Read Number of Wait states0 0000b: Wait states (Dummy Clocks) not support3DH15.083BH3BH(1-2-2) Fast Read Number of Mode Bits000b: Mode Bits not support3EH20:1600010b(1-2-2) Fast Read Number of Mode Bits000b: Mode Bits not support3EH31:24BBHBBH(1-2-2) Fast Read Opcode0-not support 1=support3FH31:24BBHBBH(2-2-2) Fast Read0-not support 1=support0000.00.0111b(4-4-4) Fast Read0-not support 1=support0.0000.00.87FH(2-2-2) Fast Read Number of Wait states0.000b: Wait states (Dummy Clocks) not support45H:44H15:000xFFH0xFFH(2-2-2) Fast Read Number of Mode Bits0.000b: Mode Bits not support46H15:000xFFH0.0FFH(2-2-2) Fast Read Number of Mode Bits0.00b: Mode Bits not support49H:48H15:000xFFH0.0FFH(2-2-2) Fast Read Number of Mode Bits0.00b: Mode Bits not support49H:48H15:000xFFH0.0FFH(2-2-2) Fast Read Number of Mode Bits0.000b: Wait states (Dummy Clocks) not support49H:48H15:000xFFH0.0FFH(2-2-2) Fast Read Number of Mode Bits0.000b: Mode Bits not support49H:48H15:000xFFH0.0FFH(4-4-4) Fast Read Number 	(1-1-2) Fast Read Number	000b: Mode Bits not support	5011	07:05	000b	0011
(1-2-2) Fast Read Number of Wait states 0 0000b: Wait states (Dummy Clocks) not support 3H 20:16 00010b 42H (1-2-2) Fast Read Number of Mode Bits 000b: Mode Bits not support 3FH 31:24 BBH BBH (2-2) Fast Read Opcode 0=not support 1=support 40H 000 0b (4-4.4) Fast Read 0=not support 1=support 40H 04 1b FEH Unused 0 000b: Wait states (Dummy (4-4.4) Fast Read 0=not support 40H 04 1b FEH Unused 0 000b: Wait states (Dummy (2-2-2) Fast Read Number 0000b: Wait states (Dummy of Mode Bits 000b: More Bits not support 46H 15:00 0xFFH	of Mode Bits			07.00	0005	
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UnusedIndexImage: Additional ad	Unused		-	07:05	111b	
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statesClocks) not support $_{4AH}$ $_{4AH}$ $_{23:21}$ $_{010b}$ $_{44H}$ (r(4-4-4) Fast Read Number of Mode Bits000b: Mode Bits not support4BH31:24EBHEBH(4-4-4) Fast Read Opcode4BH31:24EBHEBHSector Type 1 SizeSector/block size=2^N bytes 0x00b: this sector type don't exist4CH07:000CH0CHSector Type 1 erase Opcode4DH15:0820H20HSector Type 2 SizeSector/block size=2^N bytes 0x00b: this sector type don't exist4EH23:160FH0FHSector Type 2 erase OpcodeSector/block size=2^N bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 3 SizeSector/block size=2^N bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 3 erase OpcodeSector/block size=2^N bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 4 SizeSector/block size=2^N bytes 0x00b: this sector type don't exist52H23:1600H00H	(4-4-4) Fast Read Number of Wait	0 0000b: Wait states (Dummy		20.16	001005	
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Sector Type 2 erase OpcodeSector/block size=2^N bytes 0x00b: this sector type don't exist4FH31:2452H52HSector Type 3 SizeSector/block size=2^N bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 3 erase Opcode51H15:08D8HD8HSector Type 4 SizeSector/block size=2^N bytes 0x00b: this sector type don't exist52H23:1600H00H	Sector Type 2 Size		4EH	23:16	0FH	0FH
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Sector/block size=2^N bytes 52H 23:16 00H 00H	Sector Type 3 Size		50H	07:00	10H	10H
Sector Type 4 Size 0x00b: this sector type don't exist 52H 23:16 00H 00H	Sector Type 3 erase Opcode		51H	15:08	D8H	D8H
Sector Type 4 Size 0x00b: this sector type don't exist 52H 23:16 00H 00H		Sector/block size=2^N bytes				
	Sector Type 4 Size	-	52H	23:16	00H	00H
Sector Type 4 erase Opcode53H31:24FFH	Sector Type 4 erase Opcode		53H	31:24	FFH	FFH

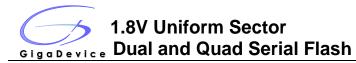


Table5. Parameter Table (1): GigaDevice Flash Parameter Tables

Tables. Parameter Table (1): GigaDevice Flash Parameter Tables					
Description	Comment	Add(H) (Byte)	DW Add (Bit)	Data	Data
	2000H=2.000V	()	()		
Vcc Supply Maximum Voltage	2700H=2.700V	61H:60H	15:00	2000H	2000H
	3600H=3.600V				
	1650H=1.650V				
Vcc Supply Minimum Voltage	2250H=2.250V	63H:62H	31:16	1650H	1650H
vec Supply Minimum voltage	2350H=2.350V	0311.0211	31.10	105011	103011
	2700H=2.700V				
HW Reset# pin	0=not support 1=support		00	0b	
HW Hold# pin	0=not support 1=support		01	1b	
Deep Power Down Mode	0=not support 1=support		02	1b	
SW Reset	0=not support 1=support		03	1b	
SW Reset Opcode	Should be issue Reset Enable(66H) before Reset cmd.	65H:64H	11:04	99H	F99EH
Program Suspend/Resume	0=not support 1=support		12	1b	
Erase Suspend/Resume	0=not support 1=support		13	1b	
Unused			14	1b	
Wrap-Around Read mode	0=not support 1=support		15	1b	
Wrap-Around Read mode Opcode		66H	23:16	77H	77H
Wrap-Around Read data length	08H:support 8B wrap-around read 16H:8B&16B 32H:8B&16B&32B 64H:8B&16B&32B&64B	67H	31:24	64H	64H
Individual block lock	0=not support 1=support		00	0b	
Individual block lock bit (Volatile/Nonvolatile)	0=Volatile 1=Nonvolatile	1	01	0b	
Individual block lock Opcode		1	09:02	FFH	
Individual block lock Volatile protect bit default protect status	0=protect 1=unprotect	6BH:68H	10	0b	EBFCH
Secured OTP	0=not support 1=support]	11	1b	
Read Lock	0=not support 1=support	1	12	0b	
Permanent Lock	0=not support 1=support	1	13	1b	
Unused		1	15:14	11b	
Unused]	31:16	FFFFH	FFFFH

8. ELECTRICAL CHARACTERISTICS

8.1. POWER-ON TIMING

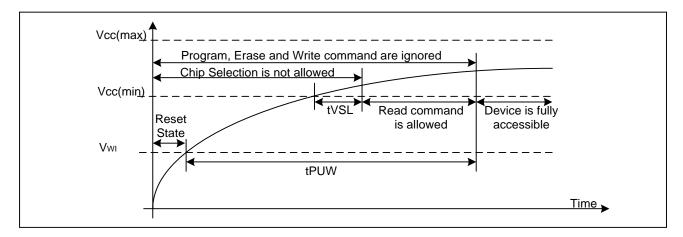


Table6. Power-Up Timing And Write Inhibit Threshold

Symbol	Parameter	Min	Max	Unit
tVSL	VCC(min) To CS# Low	10		us
tPUW	Time Delay From VCC(min) To Write Instruction	1	10	ms
VWI	Write Inhibit Voltage VCC(min)	1	1.4	V

8.2. INITIAL DELIVERY STATE

The device is delivered with the memory array erased: all bits are set to 1(each byte contains FFH). The Status Register contains 00H (all Status Register bits are 0).

8.3. DATA RETENTION AND ENDURANCE

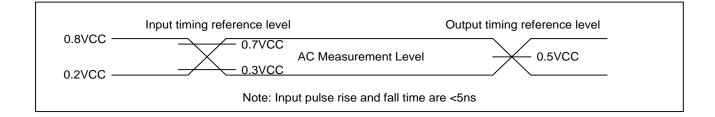
Parameter	Test Condition	Min	Units
Minimum Pattern Data Retention Time	150 ℃	10	Years
	125 ℃	20	Years
Erase/Program Endurance	-40 to 85℃	100K	Cycles

8.4. LATCH UP CHARACTERISTICS

Parameter	Min	Max
Input Voltage Respect To VSS On I/O Pins	-1.0V	VCC+1.0V
VCC Current	-100mA	100mA

8.5. ABSOLUTE MAXIMUM RATINGS

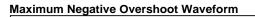
Parameter	Value	Unit
Ambient Operating Temperature	-40 to 85	°C
Storage Temperature	-65 to 150	°C
Output Short Circuit Current	200	mA
Applied Input/Output Voltage	-0.6 to VCC+0.4	V
VCC	-0.6 to VCC+0.4	V

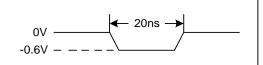


8.6. CAPACITANCE MEASUREMENT CONDITIONS

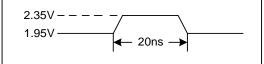
Symbol	Parameter	Min	Тур	Max	Unit	Conditions
CIN	Input Capacitance			6	pF	VIN=0V
COUT	Output Capacitance			8	pF	VOUT=0V
CL	Load Capacitance		30		pF	
	Input Rise And Fall time			5	ns	
	Input Pause Voltage	0.2VC0	C to 0.8V0	C	V	
	Input Timing Reference Voltage	0.3VCC to 0.7VCC		V		
	Output Timing Reference Voltage	0.5VCC			V	

Figure 43. Input Test Waveform and Measurement Level









1.8V Uniform Sector Dual and Quad Serial Flash

8.7. DC CHARACTERISTICS

(T= -40°C~85°C, VCC=1.65~2.0V)

Symbol	Parameter	Test Condition	Min.	Тур	Max.	Unit.
lu	Input Leakage Current				±2	μA
Ilo	Output Leakage Current				±2	μA
Icc1	Standby Current	CS#=VCC,		70	100	μA
		VIN=VCC or VSS				
Icc2	Deep Power-Down Current	CS#=VCC,		2	10	μA
		VIN=VCC or VSS				
		CLK=0.1VCC / 0.9VCC				
	Operating Current (Read)	at 120MHz,		15	20	mA
50I _{CC3}		Q=Open(*1,*2,*4 I/O)				
201003		CLK=0.1VCC / 0.9VCC				
		at 80MHz,		13	18	mA
		Q=Open(*1,*2,*4 I/O)				
Icc4	Operating Current (PP)	CS#=VCC			20	mA
Icc5	Operating Current(WRSR)	CS#=VCC			20	mA
Icc6	Operating Current (SE)	CS#=VCC			20	mA
Icc7	Operating Current (BE)	CS#=VCC			20	mA
VIL	Input Low Voltage		-0.5		0.3VCC	V
Vih	Input High Voltage		0.7VCC		VCC+0.4	V
Vol	Output Low Voltage	I _{OL} =100uA			0.2	V
V _{он}	Output High Voltage	I _{OH} =-100μA	VCC-0.2			V

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8.8. AC CHARACTERISTICS

(T= -40℃~85℃, VCC=1.65~2.0V, C_L=30pf)

Symbol	Parameter	Min.	Тур.	Max.	Unit.
fc	Serial Clock Frequency For: all command except for 03H	DC.		120	MHz
fR	Serial Clock Frequency For: Read(03H)	DC.		80	MHz
t _{CLH}	Serial Clock High Time	4			ns
tcll	Serial Clock Low Time	4			ns
tсьсн	Serial Clock Rise Time (Slew Rate)	0.2			V/ns
tchcL	Serial Clock Fall Time (Slew Rate)	0.2			V/ns
tslch	CS# Active Setup Time	5			ns
tснян	CS# Active Hold Time	5			ns
tsнсн	CS# Not Active Setup Time	5			ns
tcнs∟	CS# Not Active Hold Time	5			ns
tshsl	CS# High Time (read/write)	20			ns
tsнqz	Output Disable Time			6	ns
t CLQX	Output Hold Time	1.2			ns
t dvch	Data In Setup Time	2			ns
t CHDX	Data In Hold Time	2			ns
t HLCH	Hold# Low Setup Time (relative to Clock)	5			ns
tннсн	Hold# High Setup Time (relative to Clock)	5			ns
tснн∟	Hold# High Hold Time (relative to Clock)	5			ns
tсннн	Hold# Low Hold Time (relative to Clock)	5			ns
t HLQZ	Hold# Low To High-Z Output			6	ns
tннqх	Hold# Low To Low-Z Output			6	ns
t CLQV	Clock Low To Output Valid			7	ns
twnsl	Write Protect Setup Time Before CS# Low	20			ns
t SHWL	Write Protect Hold Time After CS# High	100			ns
t _{DP}	CS# High To Deep Power-Down Mode			20	μs
tres1	CS# High To Standby Mode Without Electronic Signature Read			20	μs
tres2	CS# High To Standby Mode With Electronic Signature Read			20	μs
ts∪s	CS# High To Next Command After Suspend	1		20	us
t _W	Write Status Register Cycle Time		5	30	ms
t PP	Page Programming Time		0.7	2.4	ms
t _{SE}	Sector Erase Time		90	1000	ms
t _{BE}	Block Erase Time(32K Bytes/64K Bytes)	1	0.3/0.5	1.2/1.5	s
tce	Chip Erase Time(GD25LQ256C)		200	400	s



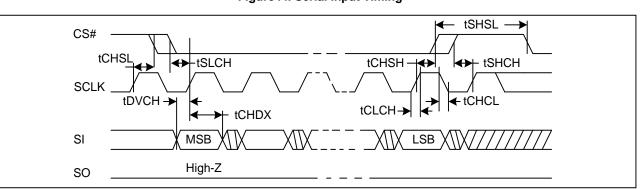


Figure44. Serial Input Timing

Figure45. Output Timing

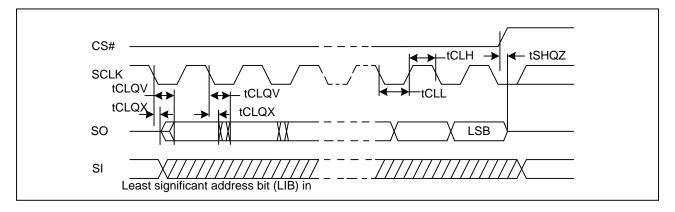
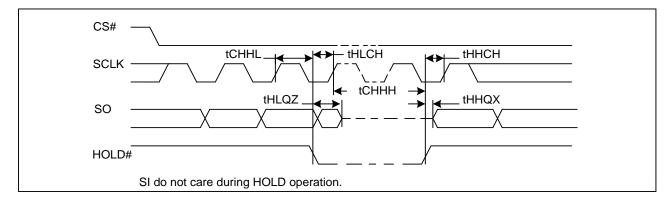
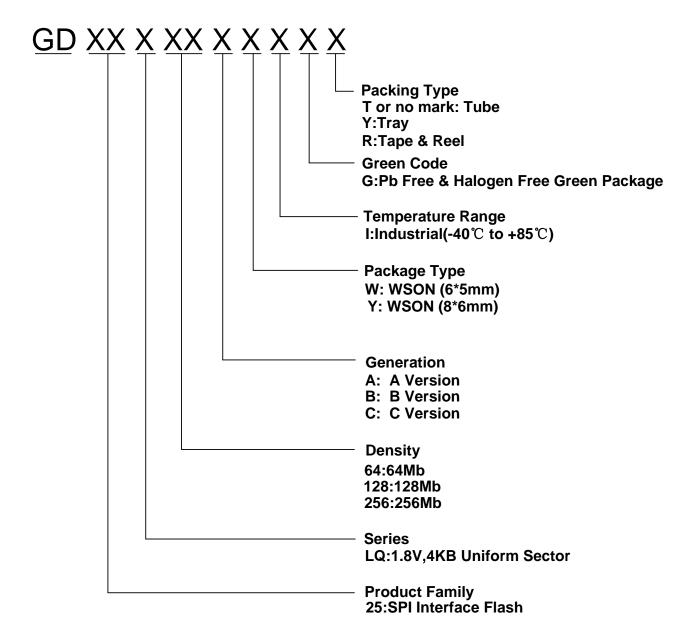


Figure46. Hold Timing

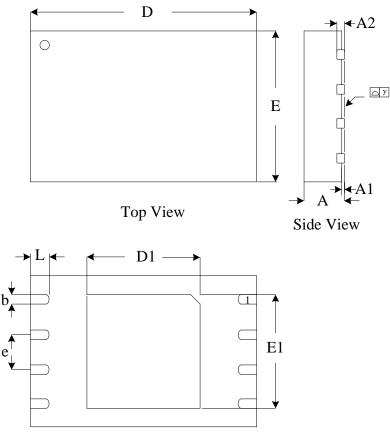


9. ORDERING INFORMATION



10. PACKAGE INFORMATION

10.1. Package WSON 8 (6*5mm)



Bottom View

Dimensions

Symb	Symbol Unit		A1	A2		-	D.	Е	E1	е	у	
Unit					b	D	D1					L
	Min	0.70		0.19	0.35	5.90	3.25	4.90	3.85		0.00	0.50
mm	Nom	0.75		0.22	0.42	6.00	3.37	5.00	3.97	1.27 BSC	0.04	0.60
	Max	0.80	0.05	0.25	0.48	6.10	3.50	5.10	4.10		0.08	0.75
	Min	0.028		0.007	0.014	0.232	0.128	0.193	0.151		0.000	0.020
Inch	Nom	0.030		0.009	0.016	0.236	0.133	0.197	0.156	0.05 BSC	0.001	0.024
	Max	0.032	0.002	0.010	0.019	0.240	0.138	0.201	0.161		0.003	0.030

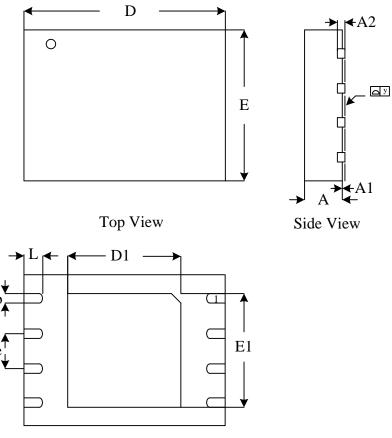
Note:

1. Both package length and width do not include mold flash.

2. The exposed metal pad area on the bottom of the package is connected to device ground (GND pin), so both Floating and connecting GND of exposed pad are also available.



Package WSON 8 (8*6mm) 10.2.



Bottom View

Dimensions

Symb	ol	•	A1	A2	h	D	D1	F	E 4		K	
Unit		A	AI	AZ	b	D		E	E1	е	K	L
	Min	0.70			0.35	7.90	3.25	5.90	4.15			0.55
mm	Nom	0.75		0.20	0.40	8.00	3.42	6.00	4.22	1.27	1.80	0.60
	Max	0.80	0.05		0.45	8.10	3.50	6.10	4.40			0.65
	Min	0.028			0.014	0.311	0.128	0.232	0.163			0.022
Inch	Nom	0.030		0.008	0.016	0.315	0.135	0.236	0.166	0.050	0.071	0.024
	Max	0.032	0.002		0.019	0.319	0.138	0.240	0.173			0.027

Note:

1. Both package length and width do not include mold flash.

2. The exposed metal pad area on the bottom of the package is connected to device ground (GND pin), so both Floating and connecting GND of exposed pad are also available.

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11. REVISION HISTORY

Version No	Description	Date		
0.0	Initial Release	2013-9-10		
0.1	Update SFDP table	2013-11-4		
0.2	Update SFDP table	2013-11-21		
	Release to normal version			
	Update AC CHARACTERISTICS: tSE typical 100ms change to 90ms			
1.0	Update AC CHARACTERISTICS: tPP typical 1ms change to 0.7ms	2014-3-5		
	Update DC CHARACTERISTICS: ICC1 typical 56ms change to 70ms			
	Delete Package WSON8 8*6mm			
	Modify Quad SPI mode description			
	Modify Data Protection description			
	Modify BP4, BP3, BP2, BP1, BP0 description			
1.1	Add note on SRP1, SRP0 bits	2014-4-28		
	Modify Security Register Address			
	Modify Command Description of 01H, 0BH and EBH			
	Add note on Read SFDP command			
	Update DC CHARACTERISTICS: Icc4, Icc5, Icc6, Icc7 max 10mA change to			
1.2	max 20mA	2014-7-11		
1.2	Update DC CHARACTERISTICS: I _{CC3} Test Condition Q=Open(*1 I/O)	2014-7-11		
	change to Q=Open(*1,*2,*4 I/O)			
1.3	Add Package WSON8 8*6mm	2014-11-17		
1.4	Modify Package WSON 8 (6*5mm)	2015-6-18		
1.4	Modify Package WSON 8 (8*6mm)	2010-0-10		